

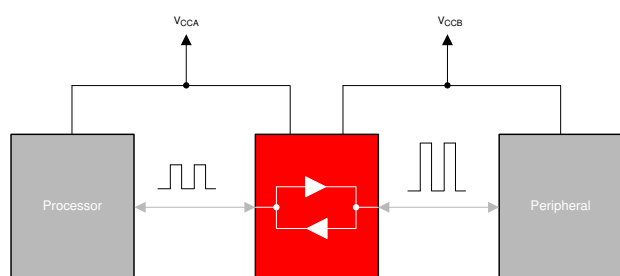
TXB0104 4 ビット双方向電圧レベルトランスレータ、自動方向検出機能および $\pm 15\text{kV}$ ESD 保護機能搭載

1 特長

- 1.2V～3.6V (A ポート)、1.65V～5.5V (B ポート) ($V_{CCA} \leq V_{CCB}$)
- V_{CC} 絶縁機能: どちらかの V_{CC} 入力がある GND レベルになると、すべての出力がハイインピーダンス状態になる
- V_{CCA} を基準とする出力イネーブル (OE) 入力回路
- 低い消費電力、最大 $I_{CC}: 5\mu\text{A}$
- I_{OFF} により部分的パワーダウン モードをサポート
- JESD 78, Class II 準拠で 100mA 超のラッチアップ性能
- JESD 22 を超える ESD 保護
 - A ポート:
 - 2500V、人体モデル (A114-B)
 - 1500V、デバイス帯電モデル (C101)
 - B ポート:
 - $\pm 15\text{kV}$ 、人体モデル (A114-B)
 - 1500V、デバイス帯電モデル (C101)

2 アプリケーション

- ヘッドセット
- スマートフォン
- タブレット
- デスクトップ PC



TXB010X の代表的なアプリケーション ブロック図

3 概要

この TXB0104 4 ビット非反転トランスレータは、設定可能な 2 本の独立した電源レールを採用しています。A ポートは V_{CCA} に追従するように設計されています。 V_{CCA} ピンには、1.2V～3.6V の電源電圧を入力できます。B ポートは、 V_{CCB} に追従する設計になっています。 V_{CCB} ピンには、1.65V～5.5V の電源電圧を入力できます。これにより、1.2V、1.5V、1.8V、2.5V、3.3V、5V の任意の電圧ノード間での自在な低電圧双方向変換が可能です。 V_{CCA} が V_{CCB} を超えないようにする必要があります。

OE 入力がある Low のとき、全出力がハイインピーダンス状態になります。電源投入時または切断時のハイインピーダンス状態を確保するには、OE をプルダウン抵抗で GND につなぐ必要があります。この抵抗の最小値は、ドライバの電流ソース能力によって決まります。

TXB0104 は、OE 入力回路が V_{CCA} によって給電されるように設計されています。

このデバイスは、 I_{OFF} を使用する部分的パワーダウン アプリケーション用に完全に動作が規定されています。 I_{OFF} 回路が出力をディセーブルにするため、電源切断時にデバイスに電流が逆流して損傷に至ることを回避できます。

パッケージ情報

部品番号 (1)	パッケージ	本体サイズ (公称)
TXB0104RUT	UQFN (12)	2.00mm × 1.70mm
TXB0104D	SOIC (14)	8.65mm × 3.91mm
TXB0104ZXU/GXU	BGA MICROSTAR JUNIOR™ (12)	2.00mm × 2.50mm
TXB0104PW	TSSOP (14)	5.00mm × 4.40mm
TXB0104RGY	VQFN (14)	3.50mm × 3.50mm
TXB0104YZT	DSBGA (12)	1.40mm × 1.90mm
TXB0104NMN	NFBGA (12)	2.00mm × 2.50mm
TXB0104BQA	WQFN (14)	3.00mm × 2.50mm
TXB0104DYY	SOT (14)	4.20mm × 2.00mm

(1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。



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4 Pin Configuration and Functions

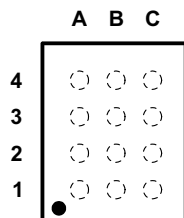


図 4-1. GXU and ZXU Package, 12-Pin BGA Microstar Junior (Top View)

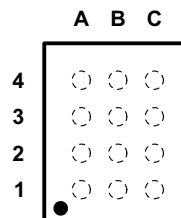


図 4-2. NMN Package, 12-Pin NFBGA (Top View)

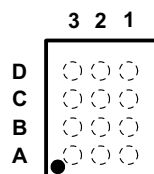
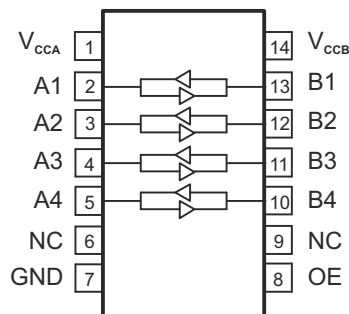
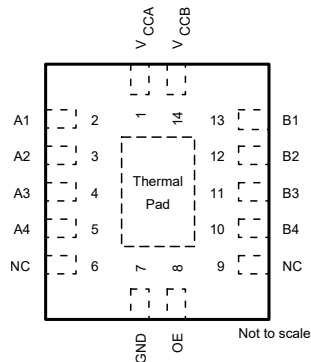


図 4-3. YZT Package, 12-Pin DSBGA (Top View)



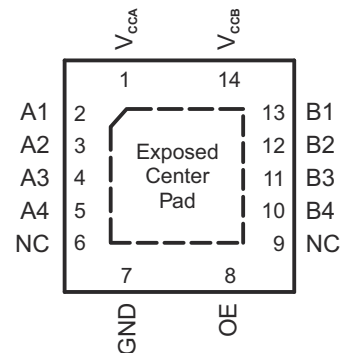
NC – No internal connection

図 4-4. D/PW/DYY Package, 14-Pin SOIC/TSSOP/SOT (Top View)



Not to scale

図 4-5. BQA Package, 14-Pin WQFN With Exposed Thermal Pad (Top View)



NC – No internal connection

図 4-6. RGY Package, 14-Pin VQFN With Exposed Thermal Pad (Top View)

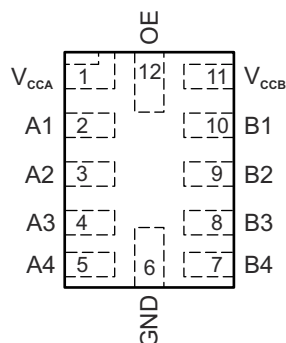


図 4-7. RUT Package, 12-Pin UQFN (Top View)

表 4-1. Pin Functions

PIN						I/O	DESCRIPTION
NAME	D, PW	BQA, RGY	RUT	GXU, ZXU, NMN	YZT		
A1	2	2	2	A1	A3	I/O	Input/output 1. Referenced to V_{CCA} .
A2	3	3	3	A2	B3	I/O	Input/output 2. Referenced to V_{CCA} .
A3	4	4	4	A3	C3	I/O	Input/output 3. Referenced to V_{CCA} .
A4	5	5	5	A4	D3	I/O	Input/output 4. Referenced to V_{CCA} .
B1	13	13	10	C1	A1	I/O	Input/output 1. Referenced to V_{CCB} .
B2	12	12	9	C2	B1	I/O	Input/output 2. Referenced to V_{CCB} .
B3	11	11	8	C3	C1	I/O	Input/output 3. Referenced to V_{CCB} .
B4	10	10	7	C4	D1	I/O	Input/output 4. Referenced to V_{CCB} .
GND	7	7	6	B4	D2	—	Ground
NC	6, 9	6, 9	—	—	—	—	No connection. Not internally connected.
OE	8	8	12	B3	C2	I	Tri-state output-mode enable. Pull OE low to place all outputs in tri-state mode. Referenced to V_{CCA} .
V_{CCA}	1	1	1	B2	B2	—	A-port supply voltage $1.2V \leq V_{CCA} \leq 3.6V$ and $V_{CCA} \leq V_{CCB}$.
V_{CCB}	14	14	11	B1	A2	—	B-port supply voltage $1.65V \leq V_{CCB} \leq 5.5V$.
Thermal pad	—	—	—	—	—	—	For the BQA, RGY package, the exposed center thermal pad must either be connected to Ground or left electrically open.

表 4-2. Pin Assignments: NMN, GXU and ZXU Package

	A	B	C
4	A4	GND	B4
3	A3	OE	B3
2	A2	V_{CCA}	B2
1	A1	V_{CCB}	B1

表 4-3. Pin Assignments: YZT Package

	3	2	1
D	A4	GND	B4
C	A3	OE	B3
B	A2	V_{CCA}	B2
A	A1	V_{CCB}	B1

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Supply voltage, V_{CCA}		−0.5	4.6	V
Supply voltage, V_{CCB}		−0.5	6.5	
Input voltage, V_I	A port	−0.5	4.6	V
	B port	−0.5	6.5	
Voltage applied to any output in the high-impedance or power-off state, V_O	A port	−0.5	4.6	V
	B port	−0.5	6.5	
Voltage applied to any output in the high or low state, V_O ⁽²⁾	A port	−0.5	$V_{CCA} + 0.5$	V
	B port	−0.5	$V_{CCB} + 0.5$	
Input clamp current, I_{IK}	$V_I < 0$		−50	mA
Output clamp current, I_{OK}	$V_O < 0$		−50	mA
Continuous output current, I_O		−50	50	mA
Continuous current through V_{CCA} , V_{CCB} , or GND		−100	100	mA
Junction temperature range, T_J			150	°C
Storage temperature range, T_{stg}		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under [セクション 5.3](#) is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	A port	±2.5	kV
	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	B port	±15	
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	A port	±1.5	
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	B port	±1.5	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

			MIN	MAX	UNIT
V _{CCA}	Supply voltage		1.2	3.6	V
V _{CCB}	Supply voltage		1.65	5.5	
V _{IH}	High-level input voltage	Data inputs	V _{CCA} = 1.2 V to 3.6 V V _{CCB} = 1.65 V to 5.5 V	V _{CCI} × 0.65 ⁽³⁾ V _{CCI}	V
		OE	V _{CCA} = 1.2 V to 3.6 V V _{CCB} = 1.65 V to 5.5 V	V _{CCA} × 0.65 5.5	
V _{IL}	Low-level input voltage	Data inputs	V _{CCA} = 1.2 V to 5.5 V V _{CCB} = 1.65 V to 5.5 V	0 V _{CCI} × 0.35 ⁽³⁾	V
		OE	V _{CCA} = 1.2 V to 3.6 V V _{CCB} = 1.65 V to 5.5 V	0 V _{CCA} × 0.35	
V _O	Voltage applied to any output in the high-impedance or power-off state	A-port	V _{CCA} = 1.2 V to 3.6 V V _{CCB} = 1.65 V to 5.5 V	0 3.6	V
		B-port	V _{CCA} = 1.2 V to 3.6 V V _{CCB} = 1.65 V to 5.5 V	0 5.5	
Δt/Δv	Input transition rise or fall rate	A-port inputs	V _{CCA} = 1.2 V to 3.6 V V _{CCB} = 1.65 V to 5.5 V	40	ns/V
		B-port inputs	V _{CCA} = 1.2 V to 3.6 V	V _{CCB} = 1.65 V to 3.6 V	40
				V _{CCB} = 4.5 V to 5.5 V	30
T _A	Operating free-air temperature		–40	85	°C

(1) The A and B sides of an unused data I/O pair must be held in the same state, that is, both at V_{CCI} or both at GND.

(2) V_{CCA} must be less than or equal to V_{CCB} and must not exceed 3.6 V.

(3) V_{CCI} is the supply voltage associated with the input port.

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TXB0104									UNIT
		D	GXU/ZXU	PW	RGY	RUT	YZT	NMN	BQA	DYY	
		14 PINS	12 PINS	14 PINS	14 PINS	12 PINS	12 PINS	12 PINS	14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	90.7	127.1	121.0	52.8	119.8	89.2	134.3	77.1	165.0	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	50.5	92.8	50.0	67.7	42.6	0.9	90.7	80.7	87.5	
R _{θJB}	Junction-to-board thermal resistance	45.4	62.2	62.8	28.9	52.5	14.4	88.4	46.9	83.2	
Ψ _{JT}	Junction-to-top characterization parameter	14.7	2.3	6.4	2.6	0.7	3.0	4.3	6.1	9.3	
Ψ _{JB}	Junction-to-board characterization parameter	45.1	62.2	62.2	29.0	52.3	14.4	89.3	46.8	83.1	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	—	—	—	—	—	—	—	23.3	-	

(1) For more information about traditional and new thermal metrics, see the [IC Package Thermal Metrics](#) application report.

5.5 Electrical Characteristics (BQA/DYY)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER ^{(1) (2)}		TEST CONDITIONS	V _{CCA}	V _{CCB}	T _A = 25°C			–40°C to 85°C		UNIT
					MIN	TYP	MAX	MIN	MAX	
V _{OHA}	Port A output high voltage	I _{OH} = –20 μA	1.2 V		1.1			V _{CCA} – 0.4		V
			1.4 V to 3.6 V							
V _{OLA}	Port A output low voltage	I _{OL} = 20 μA	1.2 V		0.3					V
			1.4 V to 3.6 V					0.4		
V _{OHB}	Port B output high voltage	I _{OH} = –20 μA		1.65 V to 5.5 V				V _{CCB} – 0.4		V
V _{OLB}	Port B output low voltage	I _{OL} = 20 μA		1.65 V to 5.5 V				0.4		V
I _I	Inflection-point current	OE: V _I = V _{CCI} or GND	1.2 V to 3.6 V	1.65 V to 5.5 V	–1		1	–2	2	μA
I _{off}	Off-state current	A port: V _I or V _O = 0 to 3.6 V	0 V	0 V to 5.5 V	–1		1	–2	2	μA
		B port: V _I or V _O = 0 to 5.5 V	0 V to 3.6 V	0 V	–1		1	–2	2	
I _{OZ}	High-impedance-state output current	A or B port: OE = GND	1.2 V to 3.6 V	1.65 V to 5.5 V	–1		1	–2	2	μA
I _{CCA}	V _{CCA} supply current	V _I = V _{CCI} or GND I _O = 0	1.2 V	1.65 V to 5.5 V	0.4					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				5		
			3.6 V	0 V				2.5		
			0 V	5.5 V				–2		
I _{CCB}	V _{CCB} supply current	V _I = V _{CCI} or GND I _O = 0	1.2 V	1.65 V to 5.5 V	3.4					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				5		
			3.6 V	0 V				–2		
			0 V	5.5 V				2		
I _{CCA} + I _{CCB}	Combined supply current	V _I = V _{CCI} or GND I _O = 0	1.2 V	1.65 V to 5.5 V	3.5					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				10		
I _{CCZA}	High-impedance state, V _{CCA} supply current	V _I = V _{CCI} or GND I _O = 0, OE = GND	1.2 V	1.65 V to 5.5 V	0.4					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				5		
I _{CCZB}	High-impedance state, V _{CCB} supply current	V _I = V _{CCI} or GND I _O = 0, OE = GND	1.2 V	1.65 V to 5.5 V	3.3					μA
			1.4 V to 3.6 V	1.65 V to 5.5 V				5		
C _i	Input capacitance	OE	1.2 V to 3.6 V	1.65 V to 5.5 V	3			6.5		pF
C _{io}	Input-to-output internal capacitance	A port	1.2 V to 3.6 V	1.65 V to 5.5 V	5			6		pF
		B port	1.2 V to 3.6 V	1.65 V to 5.5 V	11			14		

- (1) V_{CCI} is the supply voltage associated with the input port.
(2) V_{CCO} is the supply voltage associated with the output port.

5.6 Electrical Characteristics (Other Packages)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER ^{(1) (2)}	TEST CONDITIONS	V _{CCA}	V _{CCB}	T _A = 25°C			–40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
V _{OHA} Port A output high voltage	I _{OH} = –20 µA	1.2 V			1.1				V
		1.4 V to 3.6 V					V _{CCA} – 0.4		
V _{OLA} Port A output low voltage	I _{OL} = 20 µA	1.2 V			0.3				V
		1.4 V to 3.6 V						0.4	
V _{OHB} Port B output high voltage	I _{OH} = –20 µA		1.65 V to 5.5 V				V _{CCB} – 0.4		V
V _{OLB} Port B output low voltage	I _{OL} = 20 µA		1.65 V to 5.5 V					0.4	V
I _I Inflection-point current	OE: V _I = V _{CCI} or GND	1.2 V to 3.6 V	1.65 V to 5.5 V	–1		1	–2	2	µA
I _{off} Off-state current	A port: V _I or V _O = 0 to 3.6 V	0 V	0 V to 5.5 V	–1		1	–2	2	µA
	B port: V _I or V _O = 0 to 5.5 V	0 V to 3.6 V	0 V	–1		1	–2	2	
I _{OZ} High-impedance-state output current	A or B port: OE = GND	1.2 V to 3.6 V	1.65 V to 5.5 V	–1		1	–2	2	µA
I _{CCA} V _{CCA} supply current	V _I = V _{CCI} or GND I _O = 0	1.2 V	1.65 V to 5.5 V		0.06				µA
		1.4 V to 3.6 V	1.65 V to 5.5 V					5	
		3.6 V	0 V					2	
		0 V	5.5 V					–2	
I _{CCB} V _{CCB} supply current	V _I = V _{CCI} or GND I _O = 0	1.2 V	1.65 V to 5.5 V		3.4				µA
		1.4 V to 3.6 V	1.65 V to 5.5 V					5	
		3.6 V	0 V					–2	
		0 V	5.5 V					2	
I _{CCA} + I _{CCB} Combined supply current	V _I = V _{CCI} or GND I _O = 0	1.2 V	1.65 V to 5.5 V		3.5				µA
		1.4 V to 3.6 V	1.65 V to 5.5 V					10	
I _{CCZA} High-impedance state, V _{CCA} supply current	V _I = V _{CCI} or GND I _O = 0, OE = GND	1.2 V	1.65 V to 5.5 V		0.05				µA
		1.4 V to 3.6 V	1.65 V to 5.5 V					5	
I _{CCZB} High-impedance state, V _{CCB} supply current	V _I = V _{CCI} or GND I _O = 0, OE = GND	1.2 V	1.65 V to 5.5 V		3.3				µA
		1.4 V to 3.6 V	1.65 V to 5.5 V					5	
C _i Input capacitance	OE	1.2 V to 3.6 V	1.65 V to 5.5 V		3			4	pF
C _{io} Input-to-output internal capacitance	A port	1.2 V to 3.6 V	1.65 V to 5.5 V		5			6	pF
	B port	1.2 V to 3.6 V	1.65 V to 5.5 V		11			14	

5.7 Timing Requirements: $V_{CCA} = 1.2\text{ V}$

$T_A = 25^\circ\text{C}$, $V_{CCA} = 1.2\text{ V}$

			$V_{CCB} = 1.8\text{ V}$			$V_{CCB} = 2.5\text{ V}$			$V_{CCB} = 3.3\text{ V}$			$V_{CCB} = 5\text{ V}$			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
Data rate			20			20			20			20			Mbps
t_w	Pulse duration	Data inputs	50			50			50			50			ns

5.8 Timing Requirements: $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ (unless otherwise noted)

			$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate			40		40		40		40		Mbps
t_w	Pulse duration	Data inputs	25		25		25		25		ns

5.9 Timing Requirements: $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$ (unless otherwise noted)

			$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Data rate			60		60		60		60		Mbps
t_w	Pulse duration	Data inputs	17		17		17		17		ns

5.10 Timing Requirements: $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted)

			$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
Data rate			100		100		100		Mbps
t_w	Pulse duration	Data inputs	10		10		10		ns

5.11 Timing Requirements: $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$

over recommended operating free-air temperature range, $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)

			$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
			MIN	MAX	MIN	MAX	
Data rate			100		100		Mbps
t_w	Pulse duration	Data inputs	10		10		ns

5.12 Switching Characteristics: $V_{CCA} = 1.2\text{ V}$ (BQA/DYY)

$T_A = 25^\circ\text{C}$, $V_{CCA} = 1.2\text{ V}$

PARAMETER		TEST CONDITIONS	V _{CCB} = 1.8 V			V _{CCB} = 2.5 V			V _{CCB} = 3.3 V			V _{CCB} = 5 V			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t _{pd}	Propagation delay time	A-to-B	6.9			5.7			5.3			5.5			ns
		B-to-A	7.4			6.4			6			5.8			
t _{en}	Enable time	OE-to-A	1			1			1			1			μs
		OE-to-B	1			1			1			1			
t _{dis}	Disable time	OE-to-A	392			392			392			392			ns
		OE-to-B	392			392			392			392			
t _{rA} , t _{fA}	Input rise time, input fall time	A-port rise and fall times	4.2			4.2			4.2			4.2			ns
t _{rB} , t _{fB}	Input rise time, input fall time	B-port rise and fall times	2.1			1.5			1.2			1.1			ns
t _{SK(O)}	Skew (time), output	Channel-to-channel skew	0.4			0.5			0.5			1.4			ns
Maximum data rate			20			20			20			20			Mbps

5.13 Switching Characteristics: $V_{CCA} = 1.2\text{ V}$ (Other Packages)

$T_A = 25^\circ\text{C}$, $V_{CCA} = 1.2\text{ V}$

PARAMETER		TEST CONDITIONS	V _{CCB} = 1.8 V			V _{CCB} = 2.5 V			V _{CCB} = 3.3 V			V _{CCB} = 5 V			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t _{pd}	Propagation delay time	A-to-B	6.9			5.7			5.3			5.5			ns
		B-to-A	7.4			6.4			6			5.8			
t _{en}	Enable time	OE-to-A	1			1			1			1			μs
		OE-to-B	1			1			1			1			
t _{dis}	Disable time	OE-to-A	18			15			14			14			ns
		OE-to-B	20			17			16			16			
t _{rA} , t _{fA}	Input rise time, input fall time	A-port rise and fall times	4.2			4.2			4.2			4.2			ns
t _{rB} , t _{fB}	Input rise time, input fall time	B-port rise and fall times	2.1			1.5			1.2			1.1			ns
t _{SK(O)}	Skew (time), output	Channel-to-channel skew	0.4			0.5			0.5			1.4			ns
	Maximum data rate		20			20			20			20			Mbps

5.14 Switching Characteristics: $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ (BQA/DYY)

over recommended operating free-air temperature range, $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	1.4	12.9	1.2	10.1	1.1	10	0.8	9.9	ns
	B-to-A	0.9	14.2	0.7	12	0.4	11.7	0.3	13.7	
t_{en} Enable time	OE-to-A		1		1		1		1	μs
	OE-to-B		1		1		1		1	
t_{dis} Disable time	OE-to-A	278	390	236	305	236	305	236	305	ns
	OE-to-B	278	390	236	305	236	305	236	305	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5		0.5		0.5	ns
Maximum data rate		40		40		40		40		Mbps

5.15 Switching Characteristics: $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ (Other Packages)

over recommended operating free-air temperature range, $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	1.4	12.9	1.2	10.1	1.1	10	0.8	9.9	ns
	B-to-A	0.9	14.2	0.7	12	0.4	11.7	0.3	13.7	
t_{en} Enable time	OE-to-A		1		1		1		1	μs
	OE-to-B		1		1		1		1	
t_{dis} Disable time	OE-to-A	5.9	31	5.7	25.9	5.6	23	5.7	22.4	ns
	OE-to-B	5.4	30.3	4.9	22.8	4.8	20	4.9	19.5	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	1.4	5.1	1.4	5.1	1.4	5.1	1.4	5.1	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.9	4.5	0.6	3.2	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5		0.5		0.5	ns
Maximum data rate		40		40		40		40		Mbps

5.16 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (BQA/DYY)

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	1.6	11	1.4	7.7	1.3	6.8	1.2	6.5	ns
	B-to-A	1.5	12	1.3	8.4	1	7.6	0.9	7.1	
t_{en} Enable time	OE-to-A		1		1		1		1	μs
	OE-to-B		1		1		1		1	
t_{dis} Disable time	OE-to-A	278	389	191	253	190	248	189	248	ns
	OE-to-B	278	389	191	253	190	248	189	248	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	1	4.2	1.1	4.1	1.1	4.1	1.1	4.1	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.9	3.8	0.6	3.2	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5		0.5		0.5	ns
Maximum data rate		60		60		60		60		Mbps

5.17 Switching Characteristics: $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (Other Packages)

over recommended operating free-air temperature range, $V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 1.8 \text{ V} \pm 0.15 \text{ V}$		$V_{CCB} = 2.5 \text{ V} \pm 0.2 \text{ V}$		$V_{CCB} = 3.3 \text{ V} \pm 0.3 \text{ V}$		$V_{CCB} = 5 \text{ V} \pm 0.5 \text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	1.6	11	1.4	7.7	1.3	6.8	1.2	6.5	ns
	B-to-A	1.5	12	1.3	8.4	1	7.6	0.9	7.1	
t_{en} Enable time	OE-to-A		1		1		1		1	μs
	OE-to-B		1		1		1		1	
t_{dis} Disable time	OE-to-A	5.9	31	5.1	21.3	5	19.3	5	17.4	ns
	OE-to-B	5.4	30.3	4.4	20.8	4.2	17.9	4.3	16.3	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	1	4.2	1.1	4.1	1.1	4.1	1.1	4.1	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.9	3.8	0.6	3.2	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5		0.5		0.5	ns
Maximum data rate		60		60		60		60		Mbps

5.18 Switching Characteristics: $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ (BQA/DYY)

over recommended operating free-air temperature range, $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	1.1	6.3	1	5.2	0.9	4.7	ns
	B-to-A	1.2	6.6	1.1	5.1	0.9	4.4	
t_{en} Enable time	OE-to-A		1		1		1	μs
	OE-to-B		1		1		1	
t_{dis} Disable time	OE-to-A	190	252	137	184	133	169	ns
	OE-to-B	190	252	137	184	133	169	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	0.8	3	0.8	3	0.8	3	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.7	2.6	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5		0.5	ns
Maximum data rate		100		100		100		Mbps

5.19 Switching Characteristics: $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ (Other Packages)

over recommended operating free-air temperature range, $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	1.1	6.3	1	5.2	0.9	4.7	ns
	B-to-A	1.2	6.6	1.1	5.1	0.9	4.4	
t_{en} Enable time	OE-to-A		1		1		1	μs
	OE-to-B		1		1		1	
t_{dis} Disable time	OE-to-A	5.1	21.3	4.6	15.2	4.6	13.2	ns
	OE-to-B	4.4	20.8	3.8	16	3.9	13.9	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	0.8	3	0.8	3	0.8	3	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.7	2.6	0.5	2.8	0.4	2.7	ns
$t_{SK(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5		0.5	ns
Maximum data rate		100		100		100		Mbps

5.20 Switching Characteristics: $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ (BQA/DYY)

over recommended operating free-air temperature range, $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	0.9	4.7	0.8	4	ns
	B-to-A	1	4.9	0.9	3.8	
t_{en} Enable time	OE-to-A		1		1	μs
	OE-to-B		1		1	
t_{dis} Disable time	OE-to-A	137	183	97.6	127	ns
	OE-to-B	137	183	97.6	127	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	0.7	2.5	0.7	2.5	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.5	2.1	0.4	2.7	ns
$t_{sk(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5	ns
	Maximum data rate	100		100		Mbps

5.21 Switching Characteristics: $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ (Other Packages)

over recommended operating free-air temperature range, $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CCB} = 5\text{ V} \pm 0.5\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	A-to-B	0.9	4.7	0.8	4	ns
	B-to-A	1	4.9	0.9	3.8	
t_{en} Enable time	OE-to-A		1		1	μs
	OE-to-B		1		1	
t_{dis} Disable time	OE-to-A	4.6	15.2	4.3	12.1	ns
	OE-to-B	3.8	16	3.4	13.2	
t_{rA}, t_{fA} Input rise time, input fall time	A-port rise and fall times	0.7	2.5	0.7	2.5	ns
t_{rB}, t_{fB} Input rise time, input fall time	B-port rise and fall times	0.5	2.1	0.4	2.7	ns
$t_{sk(O)}$ Skew (time), output	Channel-to-channel skew		0.5		0.5	ns
	Maximum data rate	100		100		Mbps

5.22 Operating Characteristics: $V_{CCA} = 1.2\text{ V to }1.5\text{ V}$, $V_{CCB} = 1.5\text{ V to }1.8\text{ V}$

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS		V _{CCA} = 1.2 V, V _{CCB} =1.5 V			V _{CCA} = 1.2 V, V _{CCB} = 1.8 V			V _{CCA} = 1.5 V, V _{CCB} = 1.8 V			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
C _{pdA} Power dissipation capacitance	C _L = 0 f = 10 MHz t _r = t _f = 1 ns OE = V _{CCA} (outputs enabled)	A-port input, B-port output	7.8			10			9			pF
		B-port input, A-port output	12			11			11			
C _{pdB} Power dissipation capacitance		A-port input, B-port output	38.1			28			28			
		B-port input, A-port output	25.4			19			18			
C _{pdA} Power dissipation capacitance	C _L = 0 f = 10 MHz t _r = t _f = 1 ns OE = GND (outputs disabled)	A-port input, B-port output	0.01			0.01			0.01			pF
		B-port input, A-port output	0.01			0.01			0.01			
C _{pdB} Power dissipation capacitance		A-port input, B-port output	0.01			0.01			0.01			
		B-port input, A-port output	0.01			0.01			0.01			

5.23 Operating Characteristics: $V_{CCA} = 1.8\text{ V to }3.3\text{ V}$, $V_{CCB} = 1.8\text{ V to }5\text{ V}$

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS		V _{CCA} = 1.8 V, V _{CCB} = 1.8 V			V _{CCA} = 2.5 V, V _{CCB} = 2.5 V			V _{CCA} = 2.5 V, V _{CCB} = 5 V			V _{CCA} = 3.3 V, V _{CCB} = 3.3 V to 5 V			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
C _{pdA} Power dissipation capacitance	C _L = 0 f = 10 MHz t _r = t _f = 1 ns OE = V _{CCA} (outputs enabled)	A-port input, B-port output	8			8			8			9			pF
		B-port input, A-port output	11			11			11			11			
C _{pdB} Power dissipation capacitance		A-port input, B-port output	28			29			29			29			
		B-port input, A-port output	18			19			21			22			
C _{pdA} Power dissipation capacitance	C _L = 0 f = 10 MHz t _r = t _f = 1 ns OE = GND (outputs disabled)	A-port input, B-port output	0.01			0.01			0.01			0.01			pF
		B-port input, A-port output	0.01			0.01			0.01			0.01			
C _{pdB} Power dissipation capacitance		A-port input, B-port output	0.01			0.01			0.01			0.03			
		B-port input, A-port output	0.01			0.01			0.01			0.04			

5.24 Typical Characteristics

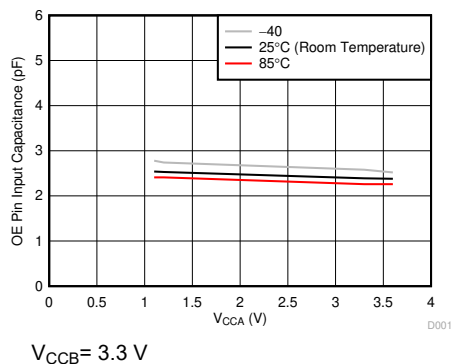


図 5-1. Input Capacitance for OE Pin (C_I) vs Power Supply (V_{CCA})

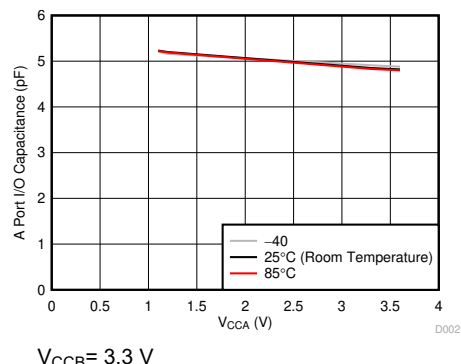


図 5-2. Capacitance for A port I/O Pins (C_{IO}) vs Power Supply (V_{CCA})

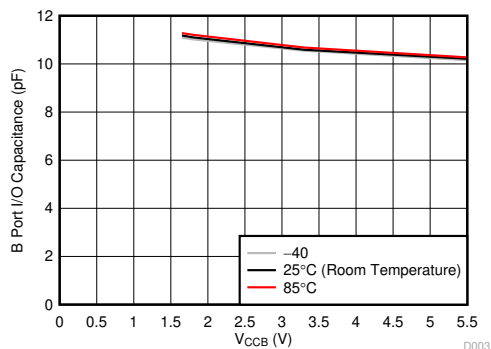


図 5-3. Capacitance for B Port I/O Pins (C_{IO}) vs Power Supply (V_{CCB})

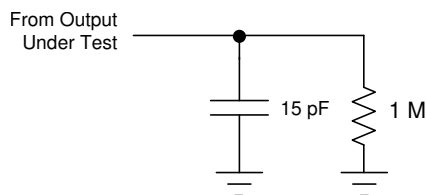
6 Parameter Measurement Information

Unless otherwise noted, all input pulses are supplied by generators that have the following characteristics:

- PRR 10 MHz
- $Z_O = 50\ \Omega$
- $dv/dt \geq 1\ \text{V/ns}$

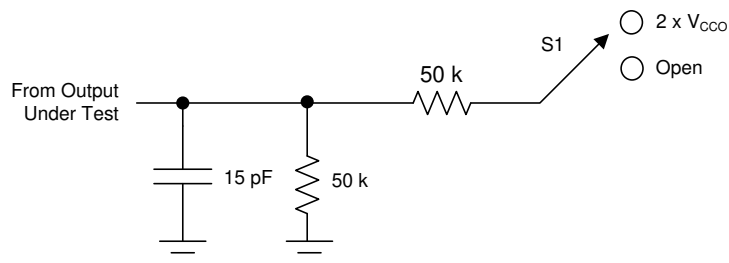
注

All parameters and waveforms are not applicable to all devices.



A. The outputs are measured one at a time, with one transition per measurement.

図 6-1. Load Circuit For Maximum Data Rate: Pulse Duration, Propagation Delay Output Rise, And Fall Time Measurement

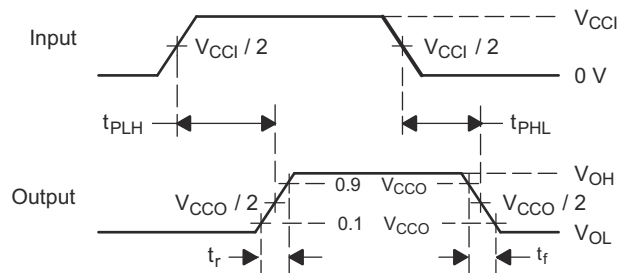


A. The outputs are measured one at a time, with one transition per measurement.

図 6-2. Load Circuit For Enable and Disable Time Measurement

表 6-1. Switch Position For Enable and Disable Time Measurement (See 図 6-2)

TEST	S1
t_{PZL}, t_{PLZ}	$2 \times V_{CCO}$
t_{PHZ}, t_{PZH}	Open



- A. V_{CCI} is the V_{CC} associated with the input port.
- B. V_{CCO} is the V_{CC} associated with the output port.
- C. t_{PLH} and t_{PHL} are the same as t_{pd} .
- D. The outputs are measured one at a time, with one transition per measurement.

図 6-3. Voltage Waveforms Propagation Delay Times

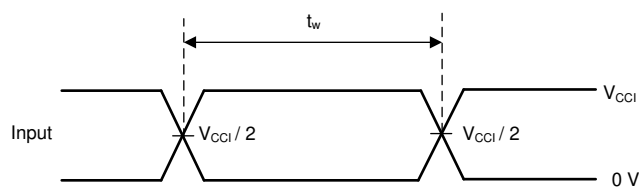


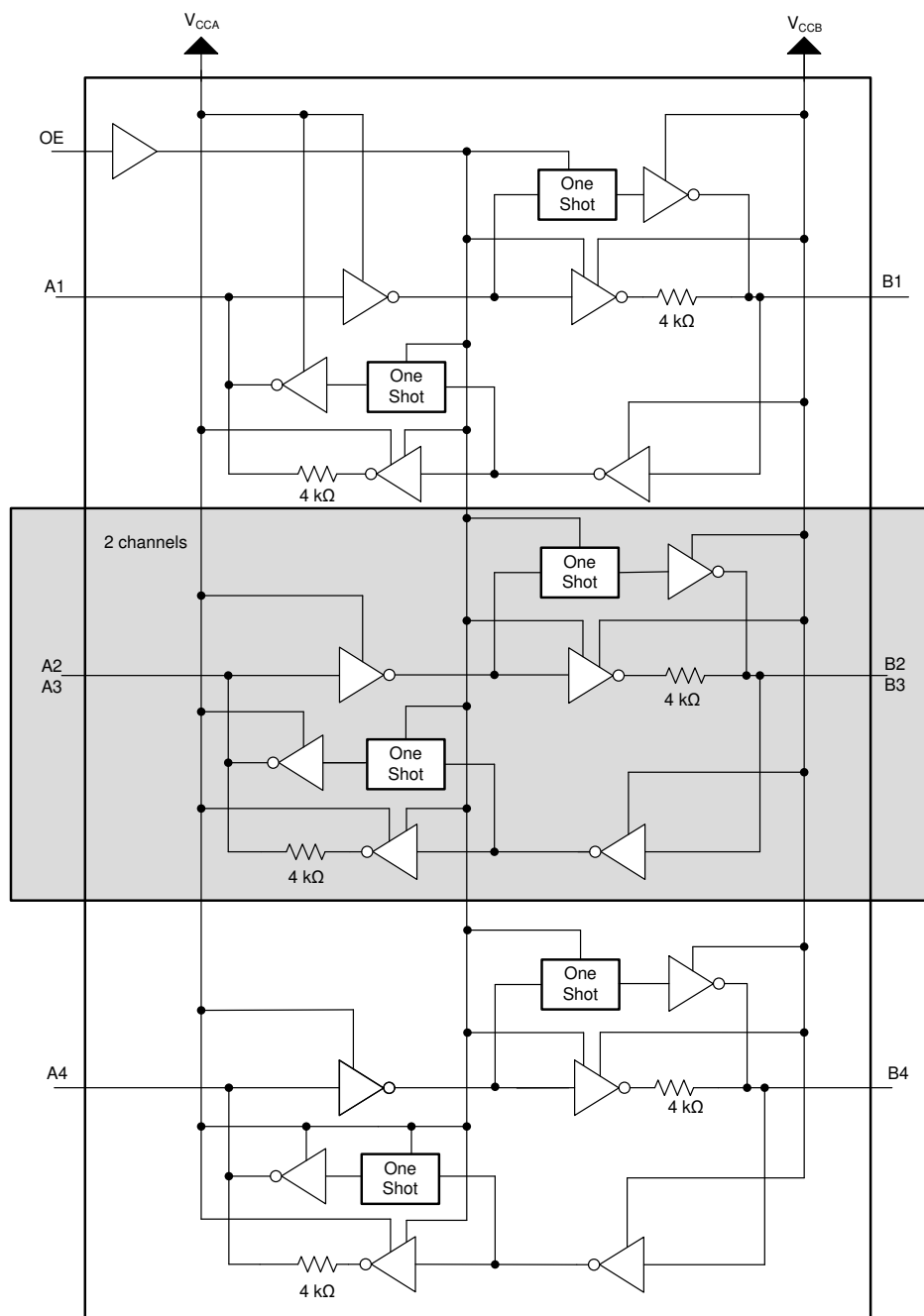
図 6-4. Voltage Waveforms Pulse Duration

7 Detailed Description

7.1 Overview

The TXB0104 device is a 4-bit, directionless voltage-level translator specifically designed for translating logic voltage levels. The A port is able to accept I/O voltages ranging from 1.2 V to 3.6 V, while the B port can accept I/O voltages from 1.65 V to 5.5 V. The device is a buffered architecture with edge-rate accelerators (one-shots) to improve the overall data rate. This device can only translate push-pull CMOS logic outputs. If for open-drain signal translation, please refer to TI's TXS010X products.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Architecture

The TXB0104 device architecture (see [Figure 7-1](#)) does not require a direction-control signal to control the direction of data flow from A to B or from B to A. In a DC state, the output drivers of the device maintain a high or low, but are designed to be weak, so the output drivers can be overdriven by an external driver when data on the bus flows the opposite direction.

The output one-shots detect rising or falling edges on the A or B ports. During a rising edge, the one-shot turns on the PMOS transistors (T1, T3) for a short duration, which speeds up the low-to-high transition. Similarly, during a falling edge, the one-shot turns on the NMOS transistors (T2, T4) for a short duration, which speeds up the high-to-low transition. The typical output impedance during output transition is 70 Ω at $V_{CCO} = 1.2$ V to 1.8 V, 50 Ω at $V_{CCO} = 1.8$ V to 3.3 V, and 40 Ω at $V_{CCO} = 3.3$ V to 5 V.

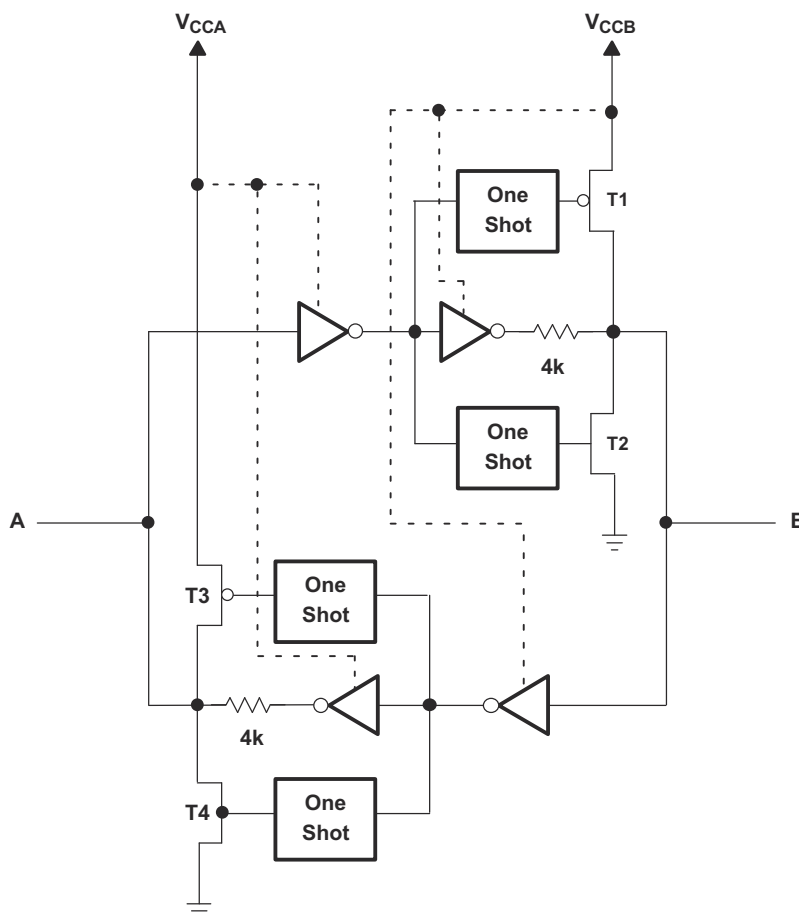
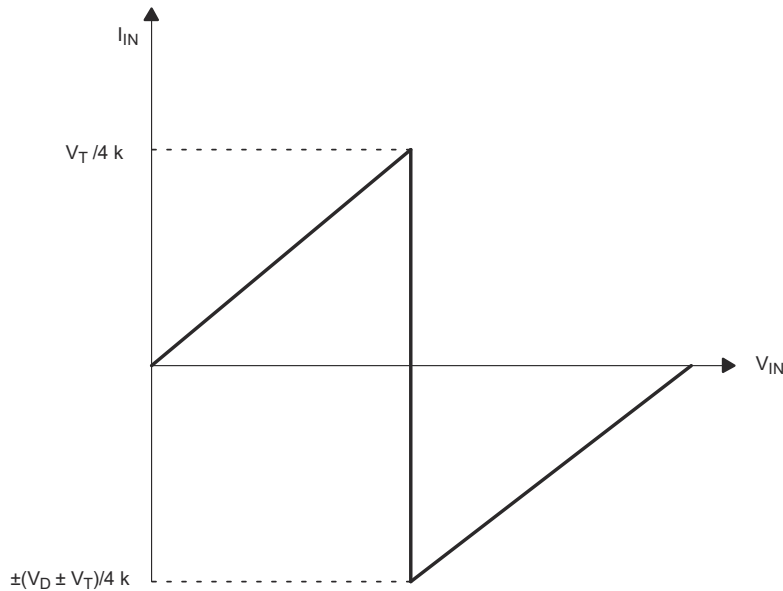


図 7-1. Architecture of TXB0104 Device I/O Cell

7.3.2 Input Driver Requirements

Typical I_{IN} vs V_{IN} characteristics of the device are shown in 7-2. For proper operation, the device driving the data I/Os of the TXB0104 device must have drive strength of at least ± 2 mA.



- A. V_T is the input threshold of the TXB0104 device, (typically $V_{CC} / 2$).
- B. V_D is the supply voltage of the external driver.

7-2. Typical I_{IN} vs V_{IN} Curve

7.3.3 Output Load Considerations

TI recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper O.S. triggering takes place. PCB signal trace-lengths must be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The O.S. circuits have been designed to stay on for approximately 10 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The O.S. duration has been set to best optimize trade-offs between dynamic ICC, load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance that the device output sees, so it is recommended that this lumped-load capacitance be considered to avoid O.S. retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

7.3.4 Enable and Disable

The TXB0104 device has an OE input that is used to disable the device by setting OE = low, which places all I/Os in the high-impedance (Hi-Z) state. The disable time (t_{dis}) indicates the delay between when OE goes low and when the outputs actually get disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

7.3.5 Pullup or Pulldown Resistors on I/O Lines

The device is designed to drive capacitive loads of up to 70 pF. The output drivers of the TXB0104 device have low dc drive strength. If pullup or pulldown resistors are connected externally to the data I/Os, their values must be kept higher than 50 k Ω to ensure that they do not contend with the output drivers of the TXB0104 device.

For the same reason, the TXB0104 device must not be used in applications such as I²C or 1-Wire where an open-drain driver is connected on the bidirectional data I/O. For these applications, use a device from the TI TXS01xx series of level translators.

7.4 Device Functional Modes

The device has two functional modes, enabled and disabled. To disable the device, set the OE input to low, which places all I/Os in a high impedance state. Setting the OE input to high will enable the device.

8 Application and Implementation

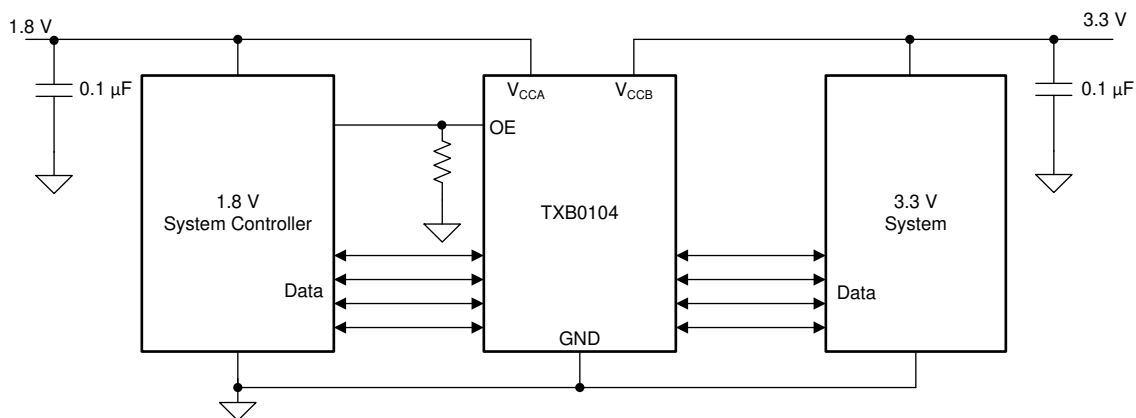
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8.1 Application Information

The TXB0104 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. It can only translate push-pull CMOS logic outputs. If for open-drain signal translation, please refer to TI TXS010X products. Any external pulldown or pullup resistors are recommended larger than 50 kΩ.

8.2 Typical Application



8.2.1 Design Requirements

For this design example, use the parameters listed in 表 8-1. And make sure the $V_{CCA} \leq V_{CCB}$.

表 8-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUE
Input voltage range	1.2 V to 3.6 V
Output voltage range	1.65 V to 5.5 V

8.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the TXB0104 device to determine the input voltage range. For a valid logic high, the value must exceed the V_{IH} of the input port. For a valid logic low, the value must be less than the V_{IL} of the input port.
- Output voltage range
 - Use the supply voltage of the device that the device is driving to determine the output voltage range.
 - External pullup or pulldown resistors are not recommended. If mandatory, it is recommended that the value must be larger than 50 k Ω .
 - An external pulldown or pullup resistor decreases the output V_{OH} and V_{OL} . Use the below equations to draft estimate the V_{OH} and V_{OL} as a result of an external pulldown and pullup resistor.

$$V_{OH} = V_{CCx} \times R_{PD} / (R_{PD} + 4.5 \text{ k}\Omega)$$

$$V_{OL} = V_{CCx} \times 4.5 \text{ k}\Omega / (R_{PU} + 4.5 \text{ k}\Omega)$$

Where

- V_{CCx} is the output port supply voltage on either V_{CCA} or V_{CCB}
- R_{PD} is the value of the external pull down resistor
- R_{PU} is the value of the external pull up resistor
- 4.5 k Ω is the counting the variation of the serial resistor 4 k Ω in the I/O line.

8.2.3 Application Curves

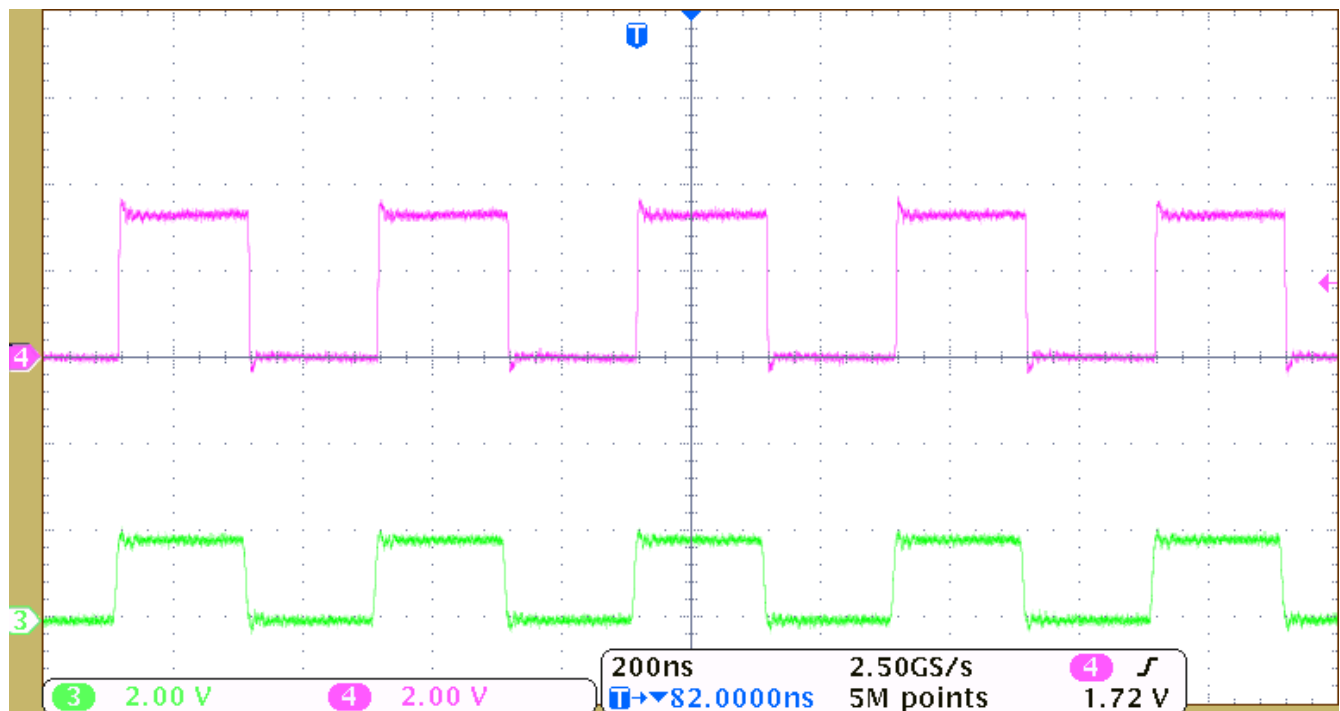


図 8-1. Level-Translation of a 2.5-MHz Signal

9 Power Supply Recommendations

During operation, ensure that $V_{CCA} \leq V_{CCB}$ at all times. During power-up sequencing, $V_{CCA} \geq V_{CCB}$ does not damage the device, so any power supply can be ramped up first. The device has circuitry that disables all output ports when either V_{CC} is switched off ($V_{CCA/B} = 0$ V). The output-enable (OE) input circuit is designed so that it is supplied by V_{CCA} and when the (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pulldown resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pulldown resistor to ground is determined by the current-sourcing capability of the driver.

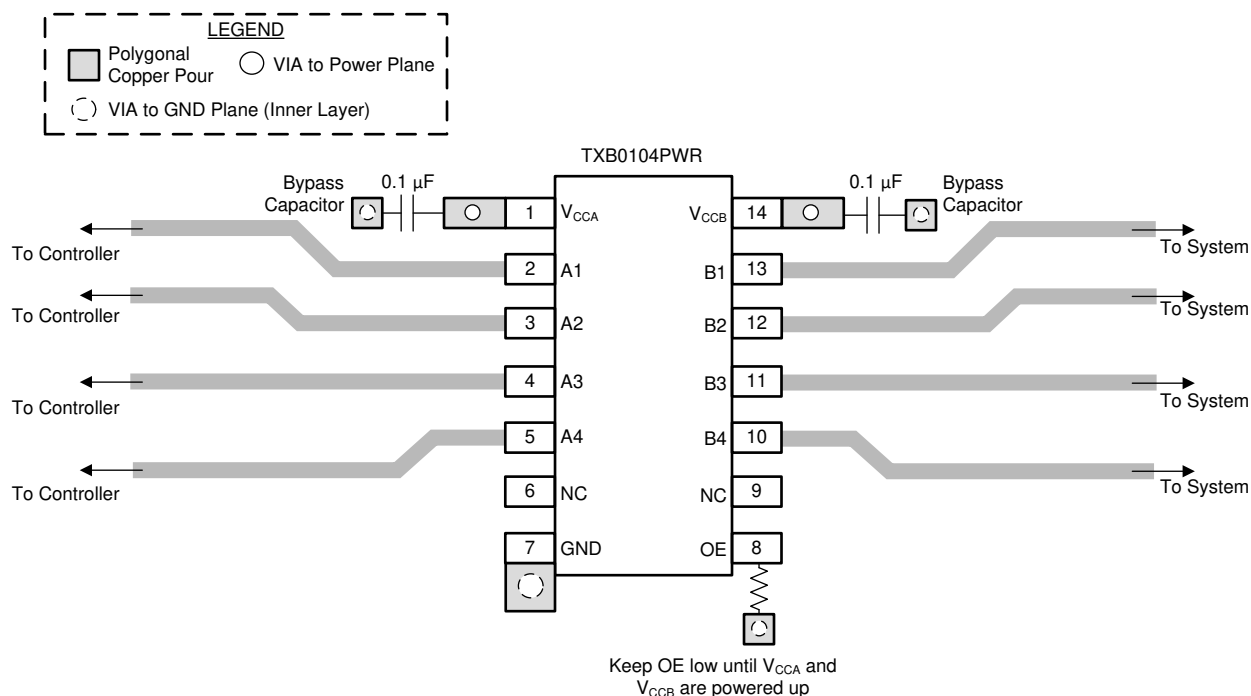
10 Layout

10.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors must be used on power supplies, and must be placed as close as possible to the V_{CCA} , V_{CCB} pin and GND pin.
- Short trace-lengths must be used to avoid excessive loading.
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one-shot duration, approximately 10 ns, ensuring that any reflection encounters low impedance at the source driver.

10.2 Layout Example



11 Device and Documentation Support

11.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

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11.5 用語集

[テキサス・インスツルメンツ用語集](#)

この用語集には、用語や略語の一覧および定義が記載されています。

12 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision J (October 2020) to Revision K (March 2025) Page

- BQA および DYY パッケージを追加..... 1
- Added thermal information for BQA and DYY packages..... 6

Changes from Revision I (March 2018) to Revision J (October 2020) Page

- ドキュメント全体にわたって表、図、相互参照の採番方法を更新..... 1
- Added NMN Package, 12-Pin NFBGA pinout drawing in *Pin Configuration and Functions* section..... 3

Changes from Revision H (January 2018) to Revision I (March 2018) Page

- Updated *Pin Functions* table 3
- Added *Pin Assignments* table for YZT package 3
- Added *Pin Assignments* table for GXU and ZXU package 3
- Updated *Layout Example* 25

Changes from Revision G (November 2014) to Revision H (January 2018) Page

- Added Package, families to Package, pinout drawings in *Pin Configuration and Functions* section 3
- Added junction temperature range in *Absolute Maximum Rating* table..... 5
- Changed unit from V to kV in *ESD Ratings* table..... 5

Changes from Revision F (May 2012) to Revision G (November 2014) Page

- 「ピン構成および機能」セクション、「取り扱いに関する定格」の表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加..... 1

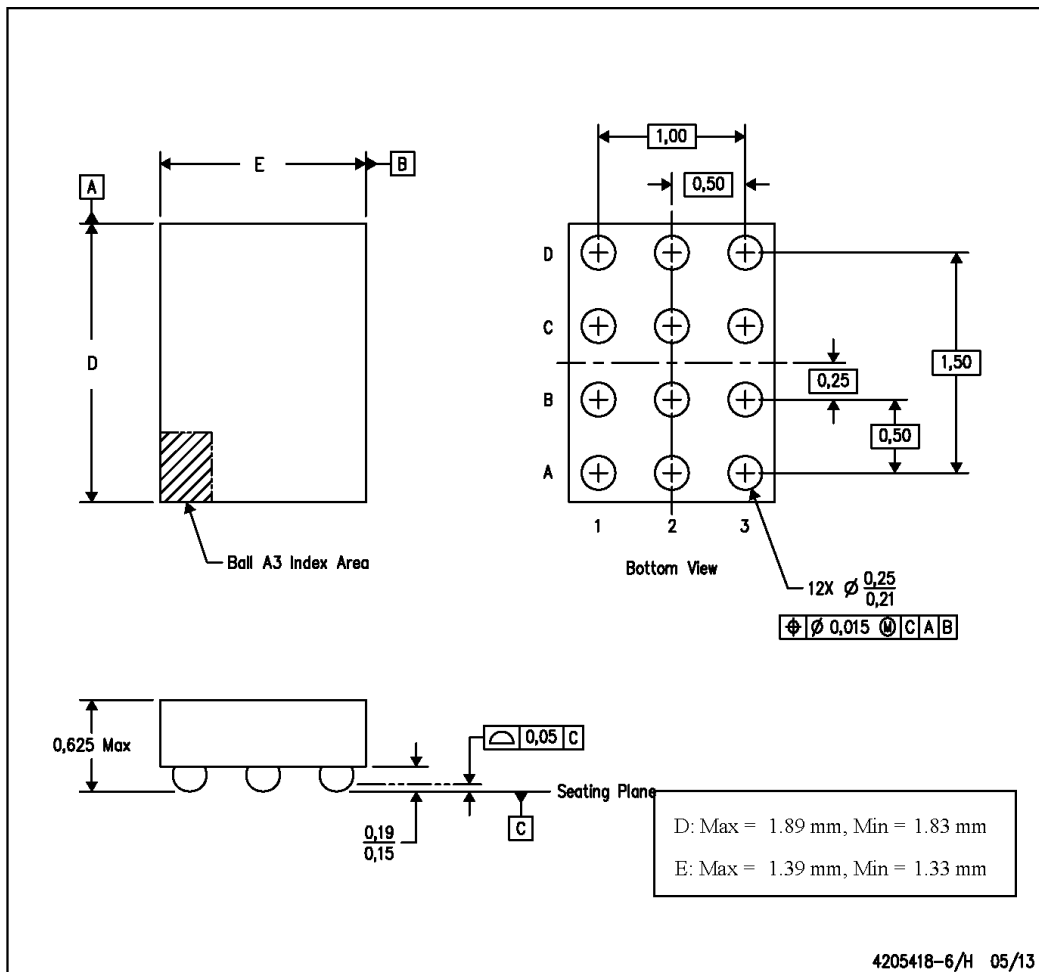
13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

MECHANICAL DATA

YZT (R-XBGA-N12)

(CUSTOM) DIE-SIZE BALL GRID ARRAY



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - NanoFree™ package configuration.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TXB0104BQAR	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YE04
TXB0104BQAR.A	Active	Production	WQFN (BQA) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YE04
TXB0104D	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104D.B	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104DG4	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104DR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104DR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104DR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104DRG4	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104DYR	Active	Production	SOT-23-THIN (DYY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TXB0104
TXB0104NMNR	Active	Production	NFBGA (NMN) 12	2500 LARGE T&R	Yes	SNAGCU	Level-2-260C-1 YEAR	-40 to 85	2AQW
TXB0104NMNR.B	Active	Production	NFBGA (NMN) 12	2500 LARGE T&R	Yes	SNAGCU	Level-2-260C-1 YEAR	-40 to 85	2AQW
TXB0104PWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YE04
TXB0104PWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YE04
TXB0104PWR.B	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YE04
TXB0104PWRG4	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YE04
TXB0104RGYR	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YE04
TXB0104RGYR.A	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YE04
TXB0104RGYR.B	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YE04
TXB0104RGYRG4	Active	Production	VQFN (RGY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	YE04
TXB0104RUTR	Active	Production	UQFN (RUT) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(2KR, 2KV)
TXB0104RUTR.A	Active	Production	UQFN (RUT) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(2KR, 2KV)
TXB0104RUTR.B	Active	Production	UQFN (RUT) 12	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	(2KR, 2KV)
TXB0104YZTR	Active	Production	DSBGA (YZT) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	2K
TXB0104YZTR.B	Active	Production	DSBGA (YZT) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	2K

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

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- Automotive : [TXB0104-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TXB0104BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
TXB0104DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TXB0104DYYR	SOT-23-THIN	DYY	14	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
TXB0104NMNR	NFBGA	NMN	12	2500	180.0	8.4	2.3	2.8	1.15	4.0	8.0	Q2
TXB0104PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TXB0104RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1
TXB0104RUTR	UQFN	RUT	12	3000	180.0	9.5	1.9	2.2	0.7	4.0	8.0	Q1
TXB0104YZTR	DSBGA	YZT	12	3000	180.0	8.4	1.49	1.99	0.75	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TXB0104BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
TXB0104DR	SOIC	D	14	2500	353.0	353.0	32.0
TXB0104DYYR	SOT-23-THIN	DYY	14	3000	336.6	336.6	31.8
TXB0104NMNR	NFBGA	NMN	12	2500	210.0	185.0	35.0
TXB0104PWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TXB0104RGYR	VQFN	RGY	14	3000	353.0	353.0	32.0
TXB0104RUTR	UQFN	RUT	12	3000	189.0	185.0	36.0
TXB0104YZTR	DSBGA	YZT	12	3000	182.0	182.0	20.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TXB0104D	D	SOIC	14	50	506.6	8	3940	4.32
TXB0104D.B	D	SOIC	14	50	506.6	8	3940	4.32
TXB0104DG4	D	SOIC	14	50	506.6	8	3940	4.32

GENERIC PACKAGE VIEW

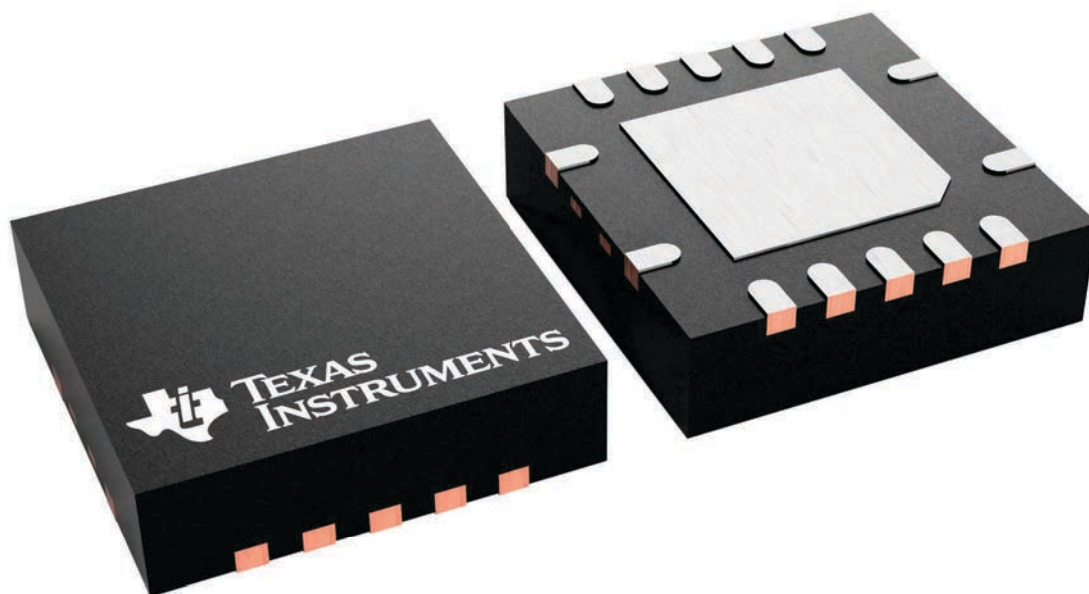
RGY 14

VQFN - 1 mm max height

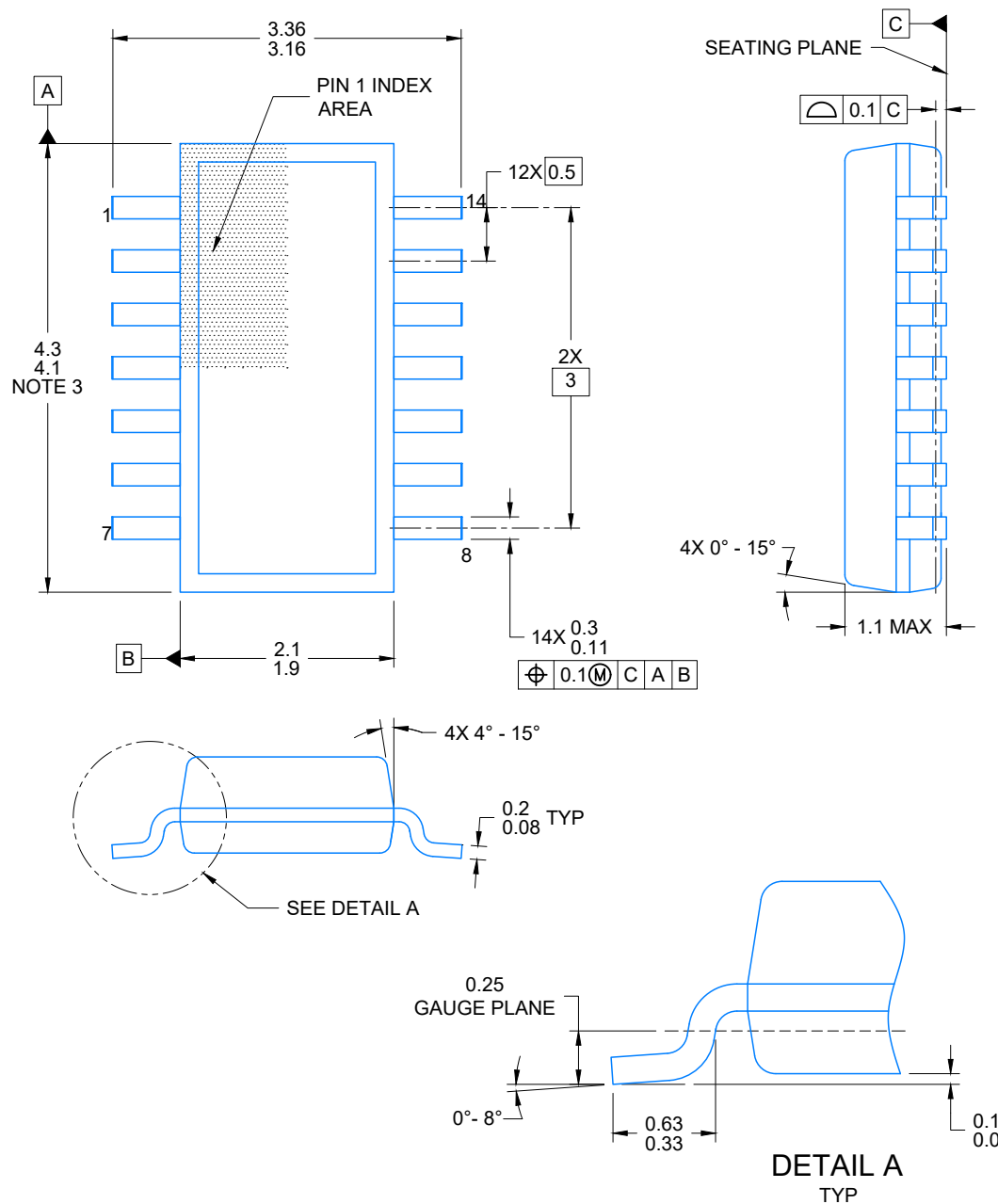
3.5 x 3.5, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



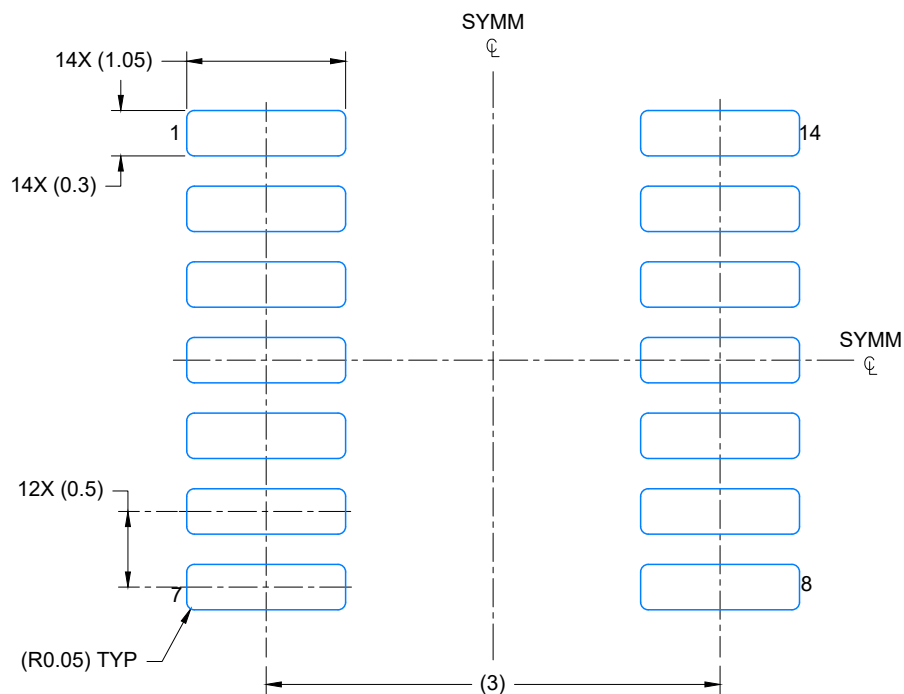
4231541/A



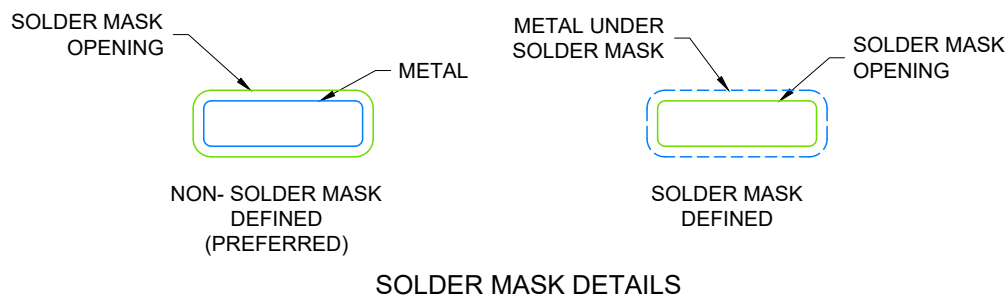
4224643/D 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AB



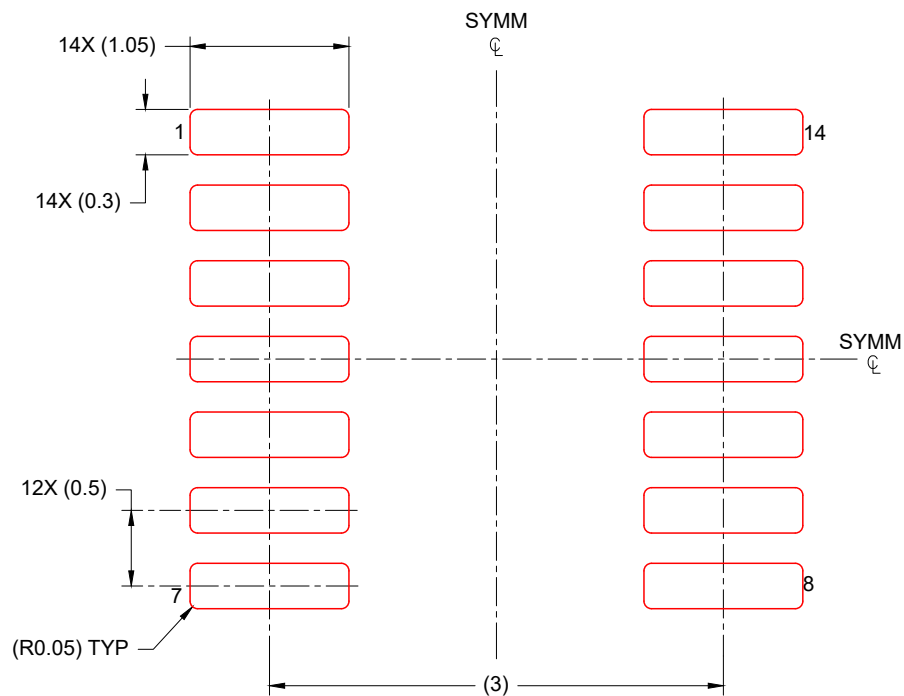
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



4224643/D 07/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

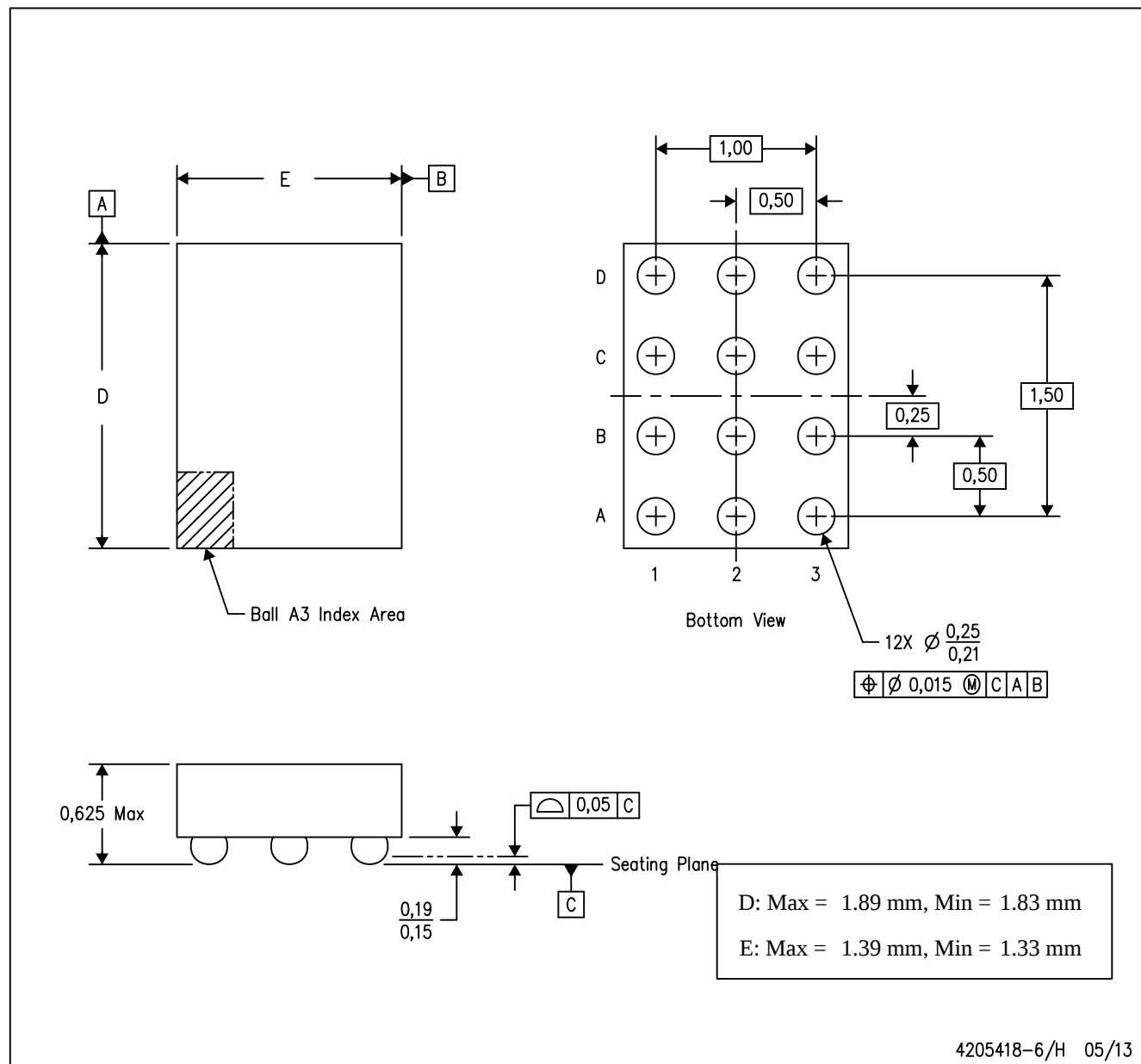
4224643/D 07/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

YZT (R-XBGA-N12)

(CUSTOM) DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

D0014A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

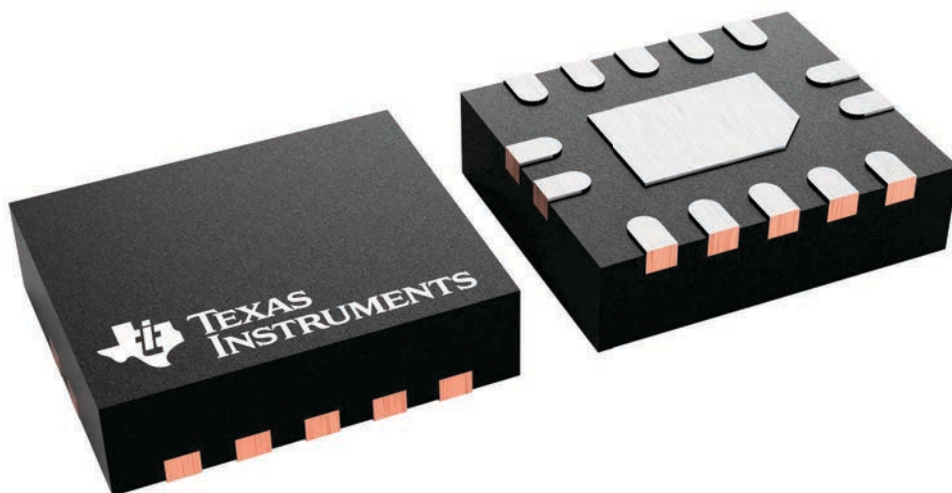
BQA 14

WQFN - 0.8 mm max height

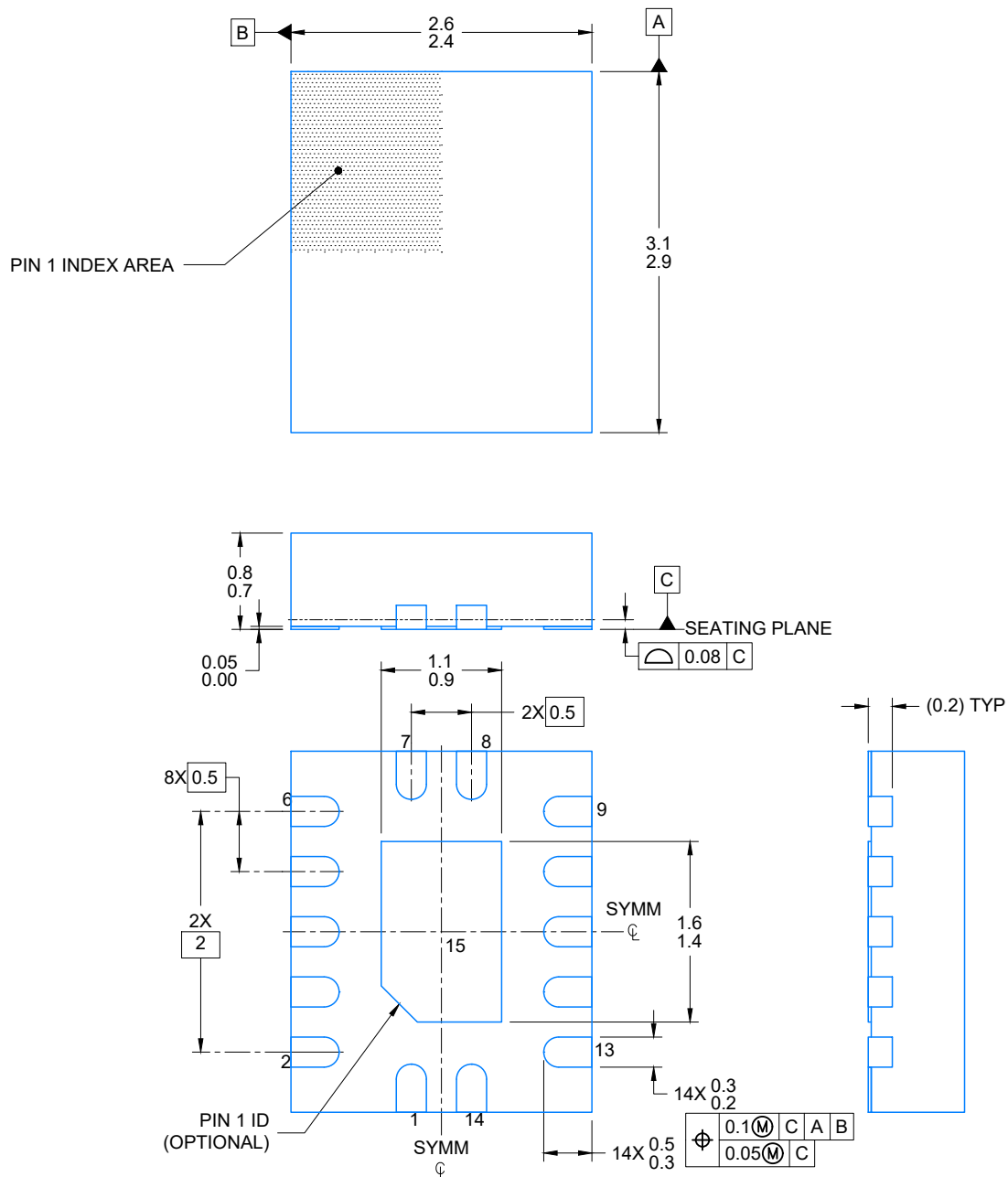
2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



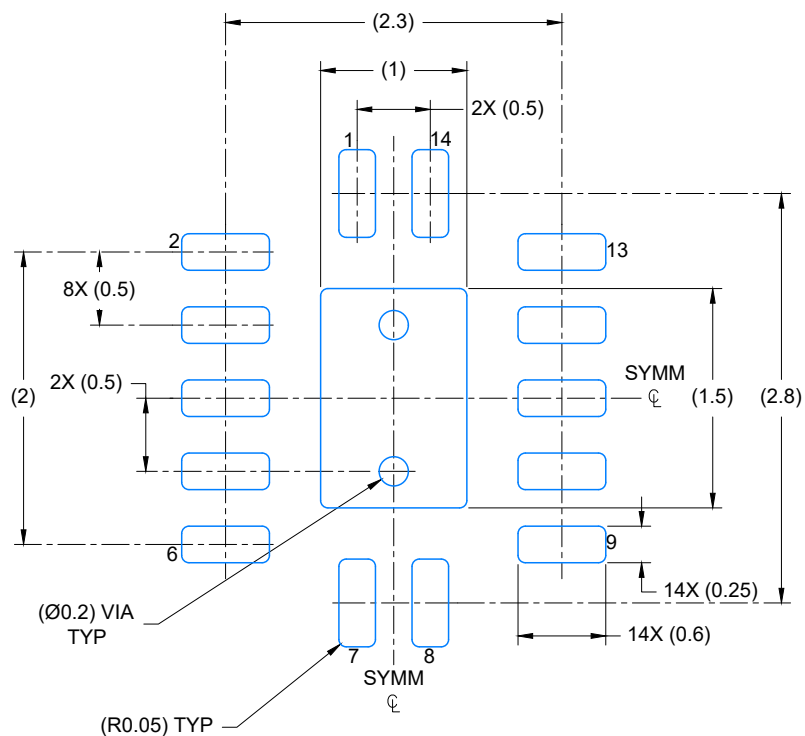
PLASTIC QUAD FLAT PACK-NO LEAD



4224636/A 11/2018

NOTES:

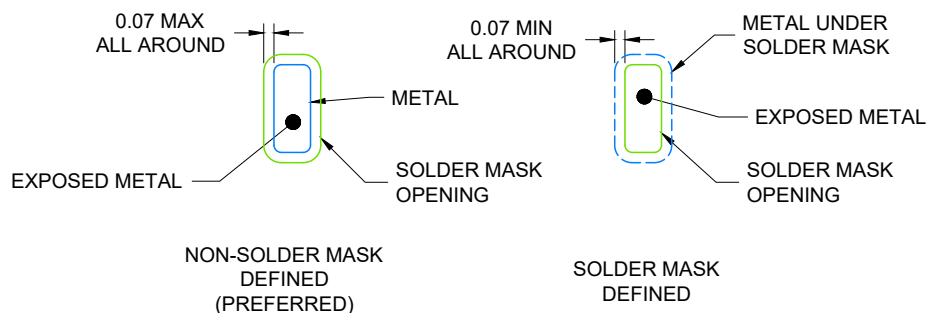
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



LAND PATTERN EXAMPLE

EXPOSED METAL SHOWN

SCALE: 20X



4224636/A 11/2018

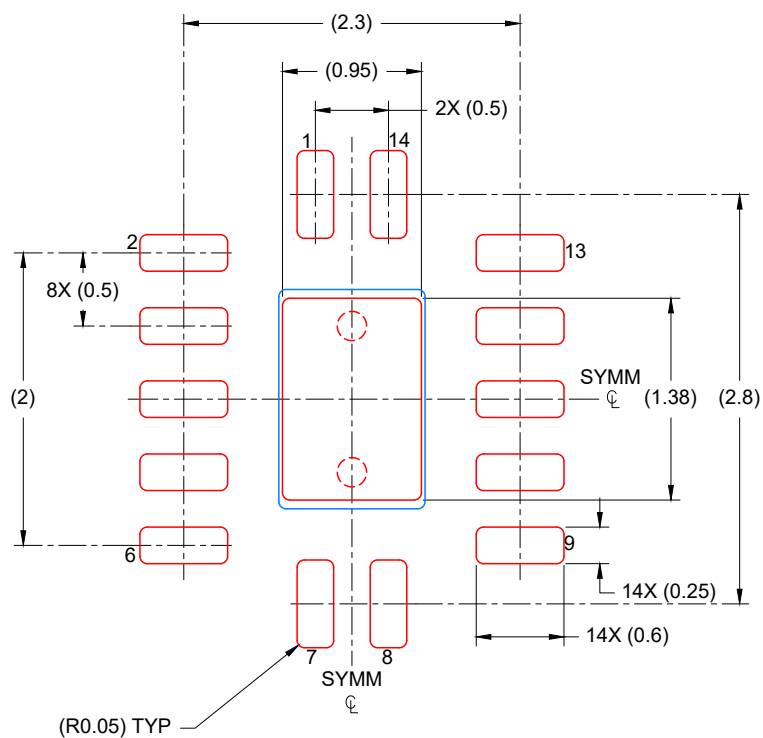
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

BQA0014A

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



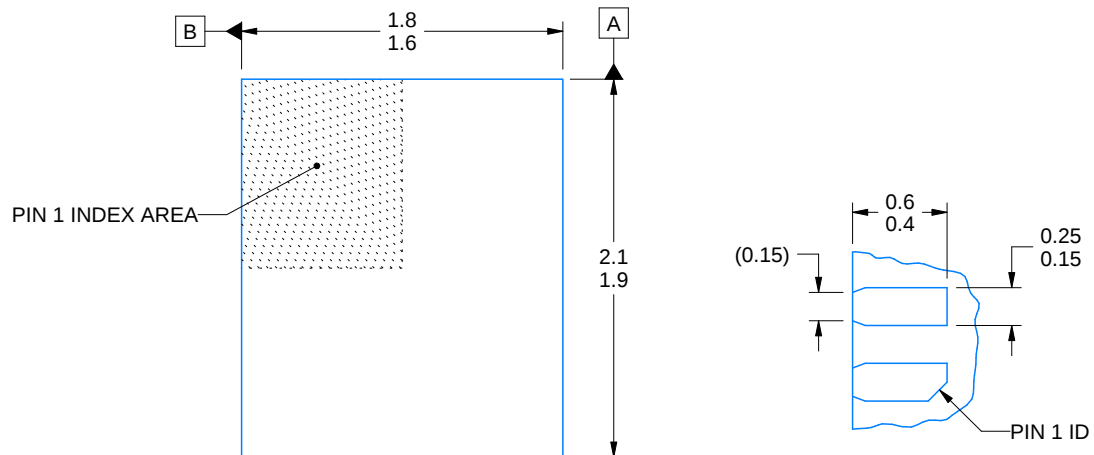
SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
88% PRINTED COVERAGE BY AREA
SCALE: 20X

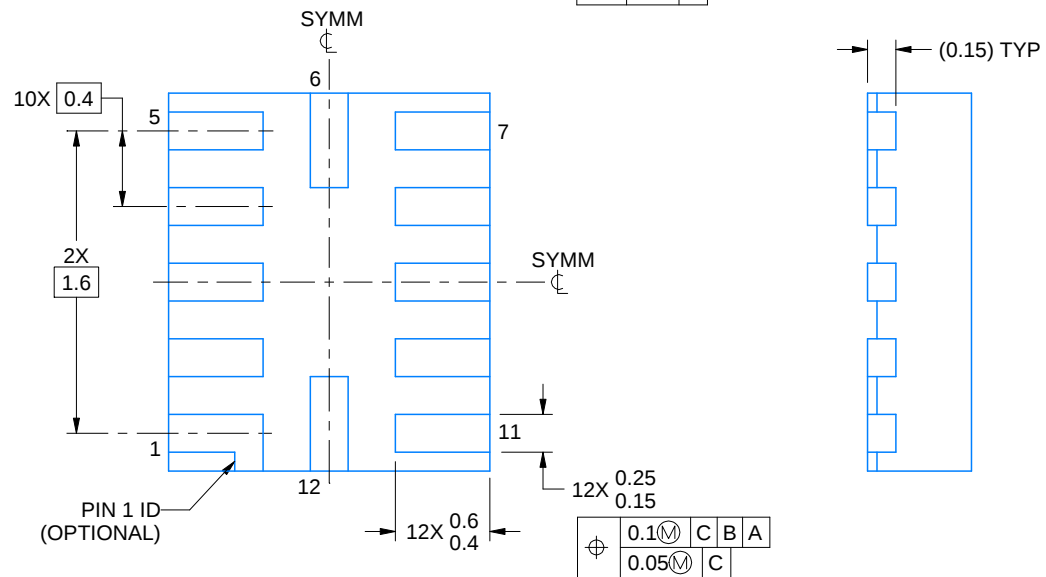
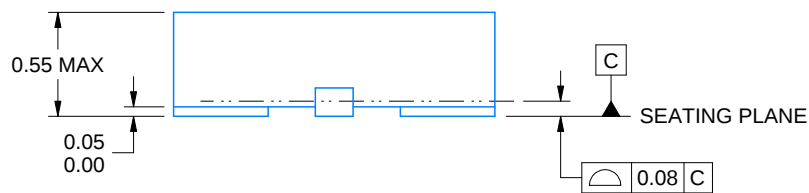
4224636/A 11/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



OPTIONAL TERMINAL & PIN 1 ID



4220310/A 11/2016

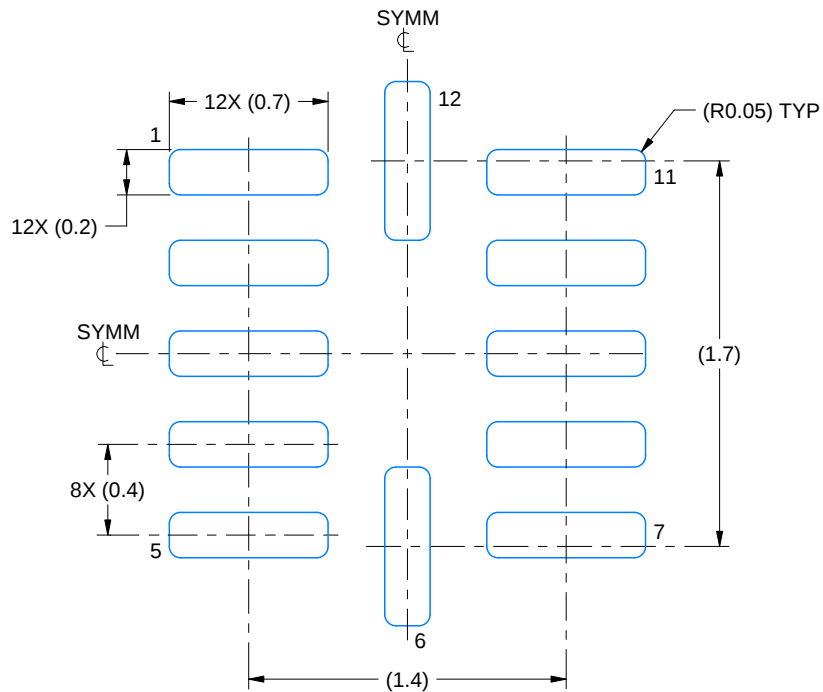
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

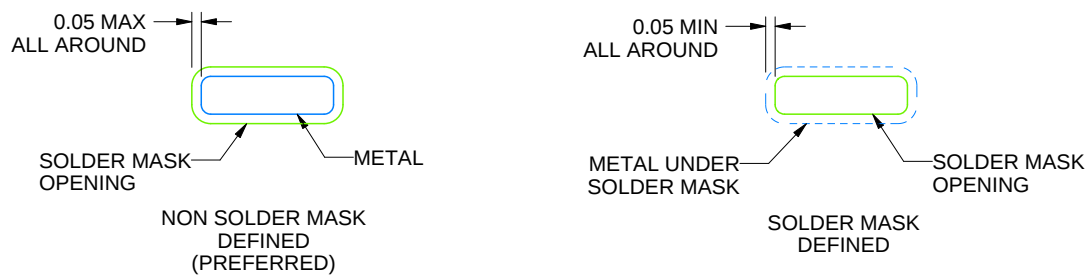
RUT0012A

UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:30X



SOLDER MASK DETAILS

4220310/A 11/2016

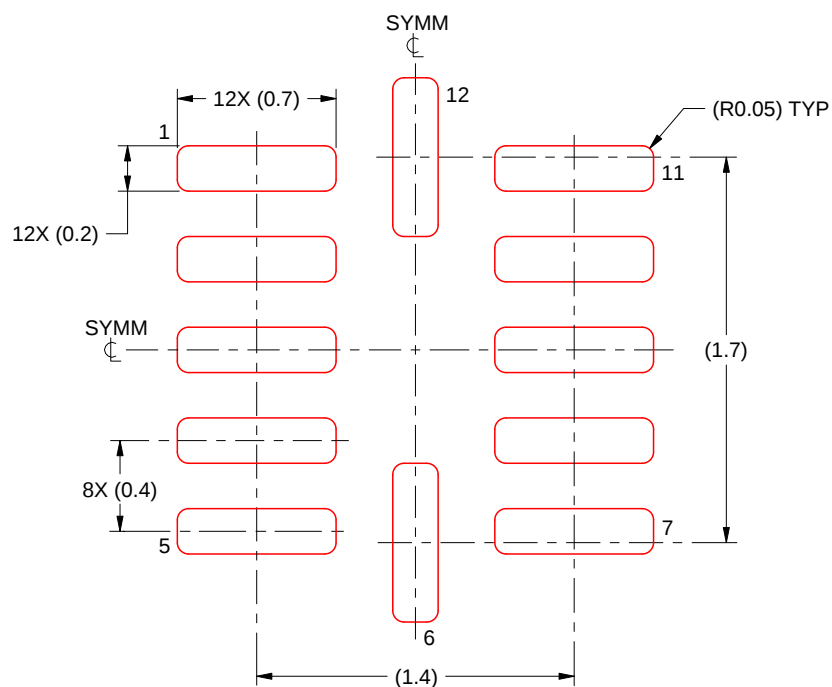
NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sl原因271).

RUT0012A

UQFN - 0.55 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

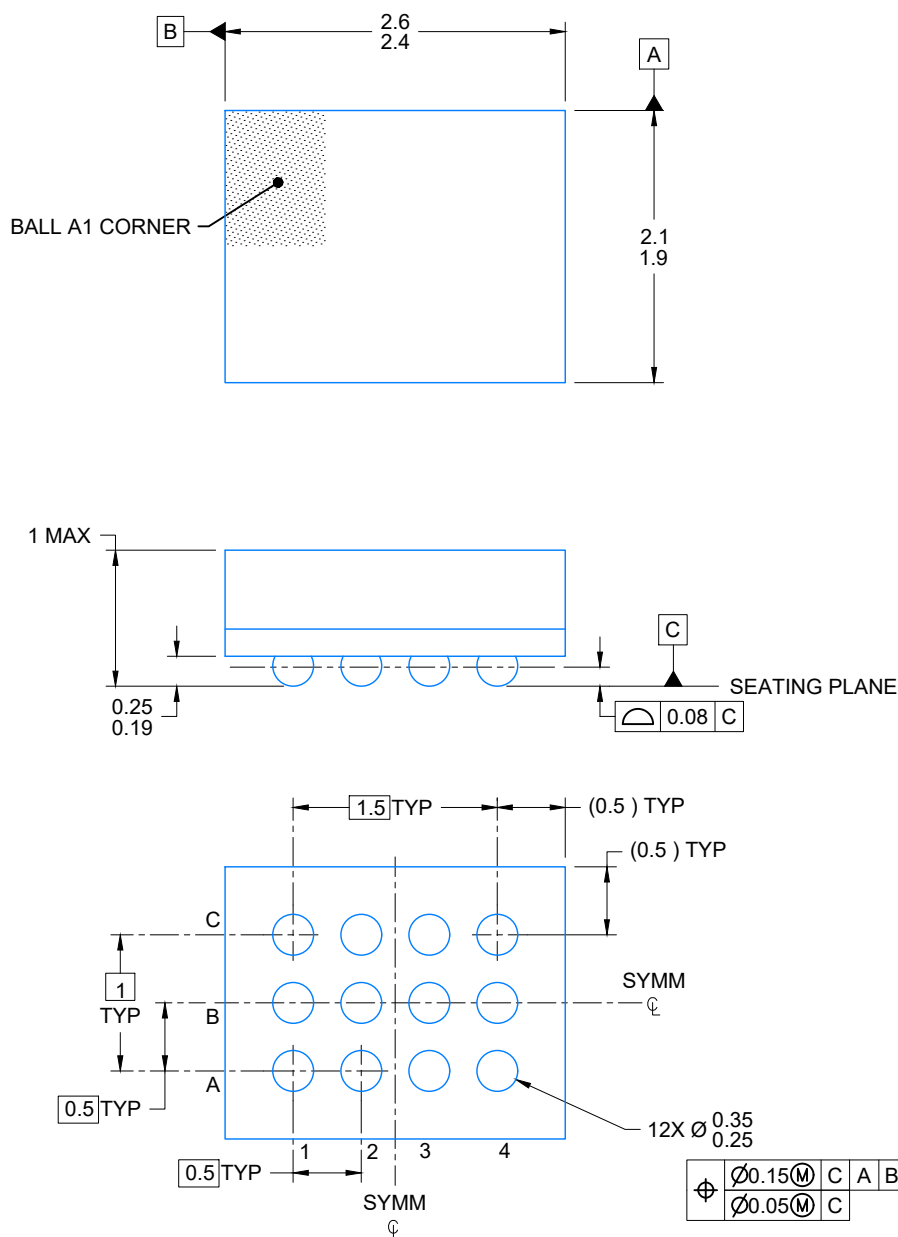


SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE: 30X

4220310/A 11/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

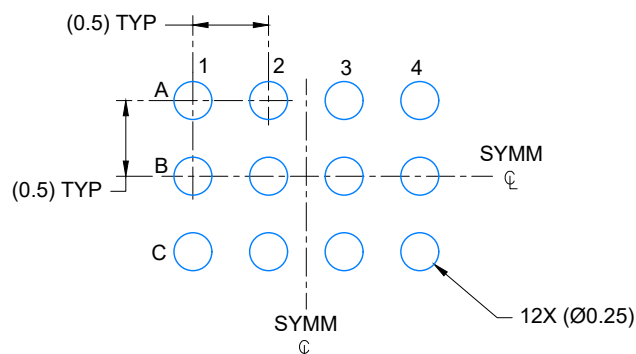


4225768/A 03/2020

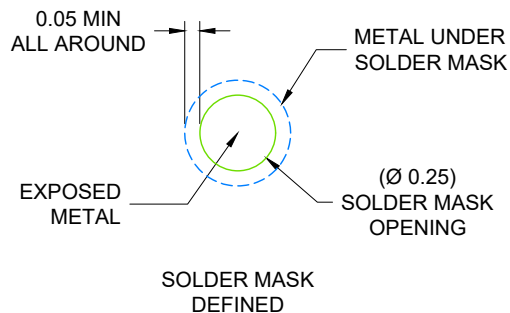
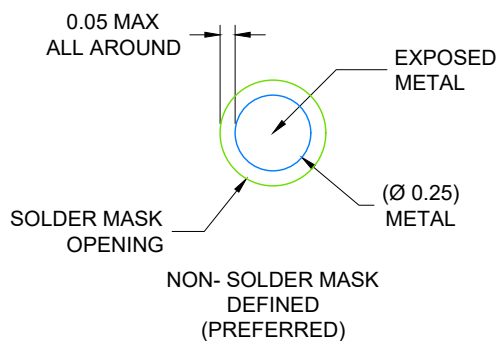
NOTES:

NanoFree is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



LAND PATTERN EXAMPLE
SCALE: 20X

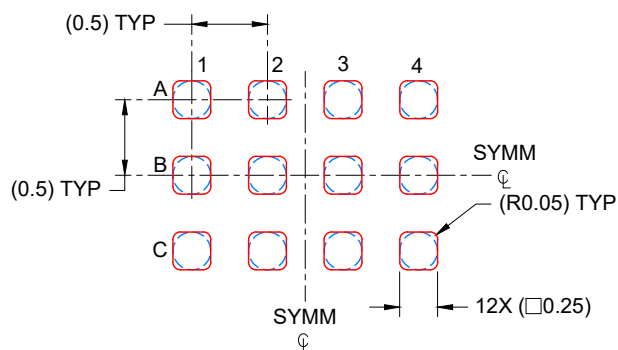


SOLDER MASK DETAILS
NOT TO SCALE

4225768/A 03/2020

NOTES: (continued)

- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. Refer to Texas Instruments Literature number SNVA009 (www.ti.com/lit/snva009).

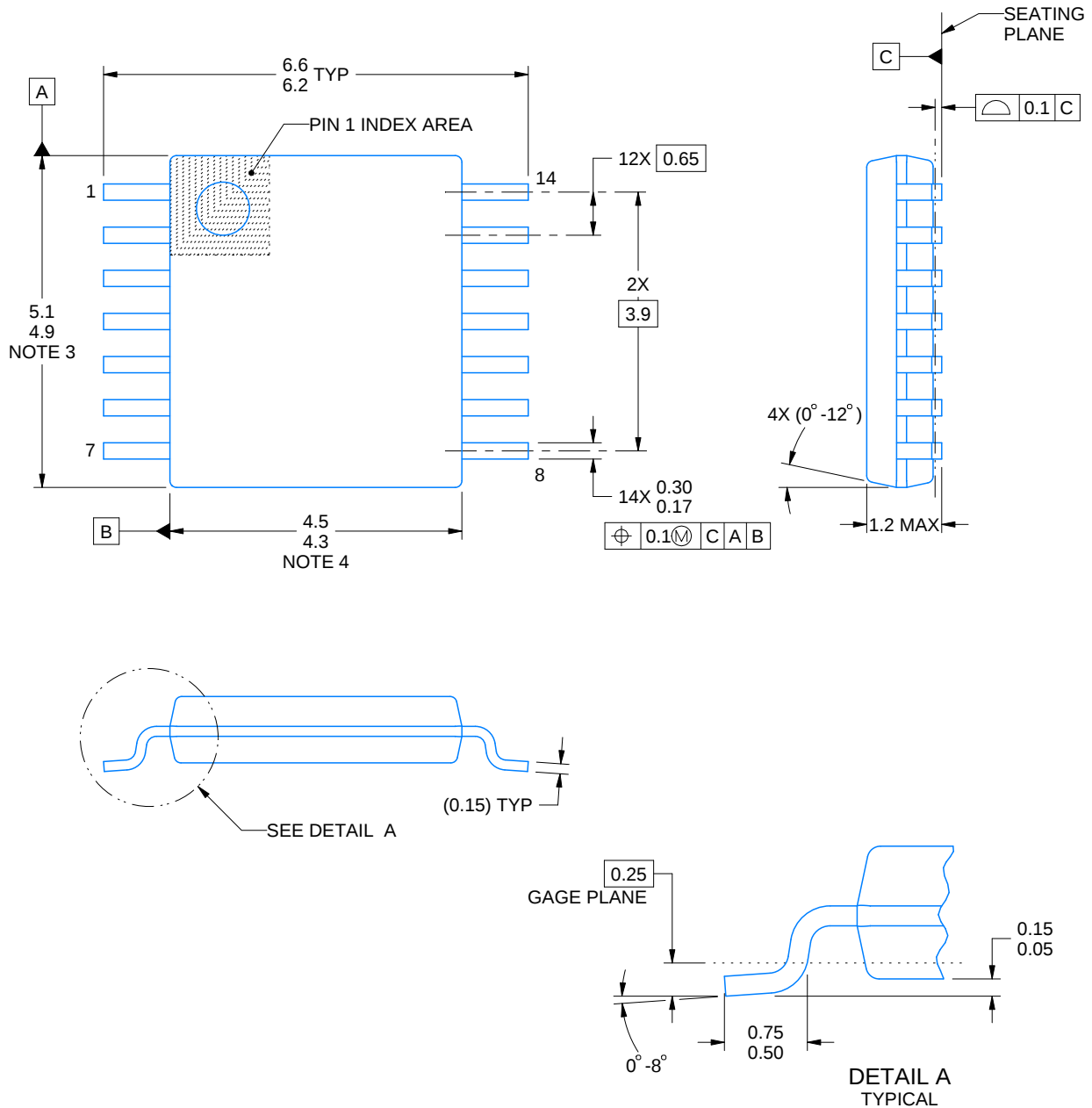
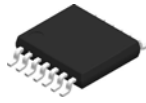


SOLDER PASTE EXAMPLE
 BASED ON 0.100 mm THICK STENCIL
 SCALE: 20X

4225768/A 03/2020

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



4220202/B 12/2023

NOTES:

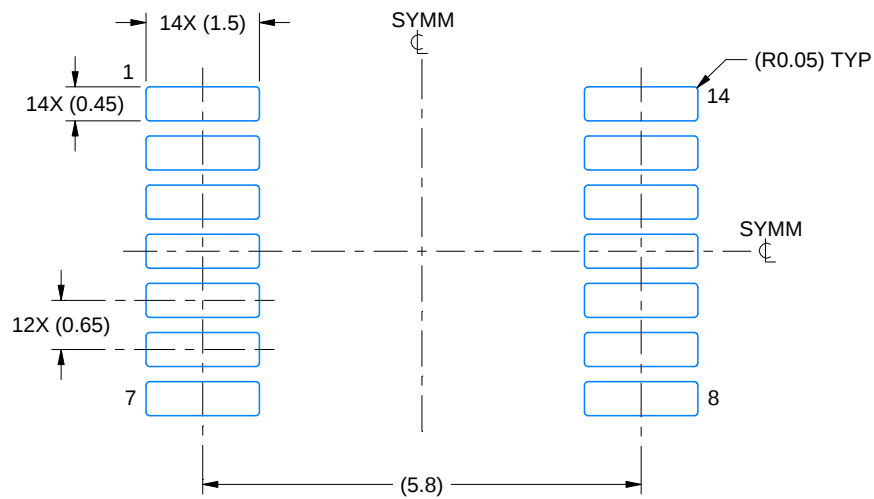
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

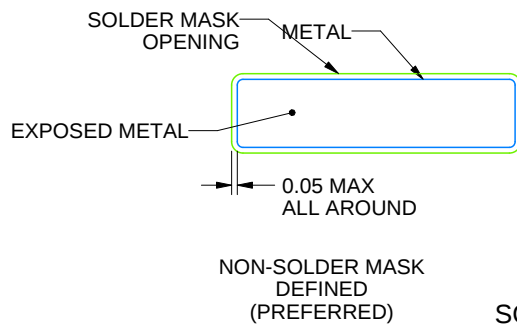
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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最終更新日：2025 年 10 月